



VSiPMT Prototype Tests

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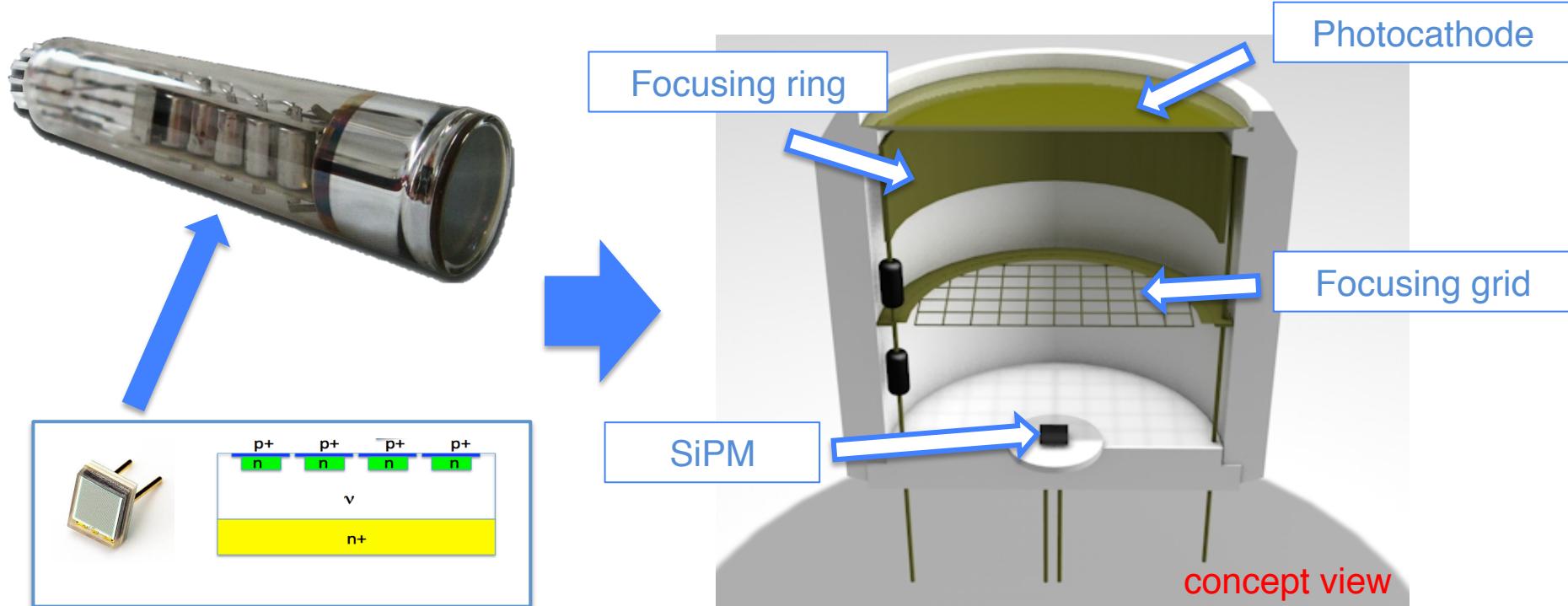
Outline

1. Introduction
2. The prototypes
3. Experimental setup
4. Characterization
5. Conclusions

Introduction

Vacuum Silicon PhotoMultiplier Tube (VSiPMT)

An innovative design for a modern hybrid photodetector based on the combination of a Silicon PhotoMultiplier (SiPM) with a Vacuum PMT standard envelope



The classical dynode chain of a PMT is replaced with a SiPM, acting as an electron multiplying detector.

An attractive solution for cryogenic applications

Requirements for next generation DM experiments

- Good bg discrimination → High S/N ratio and high SPE resolution;
- Low radioactive bg → PMTs < 1mBq/(3" PMT);
- Low power consumption;
- Stable operation at LAr/LXe temperature.

Uranium, Thorium and Potassium from ceramics/metal parts in a standard PMT are the main source of background in DM noble liquids experiments

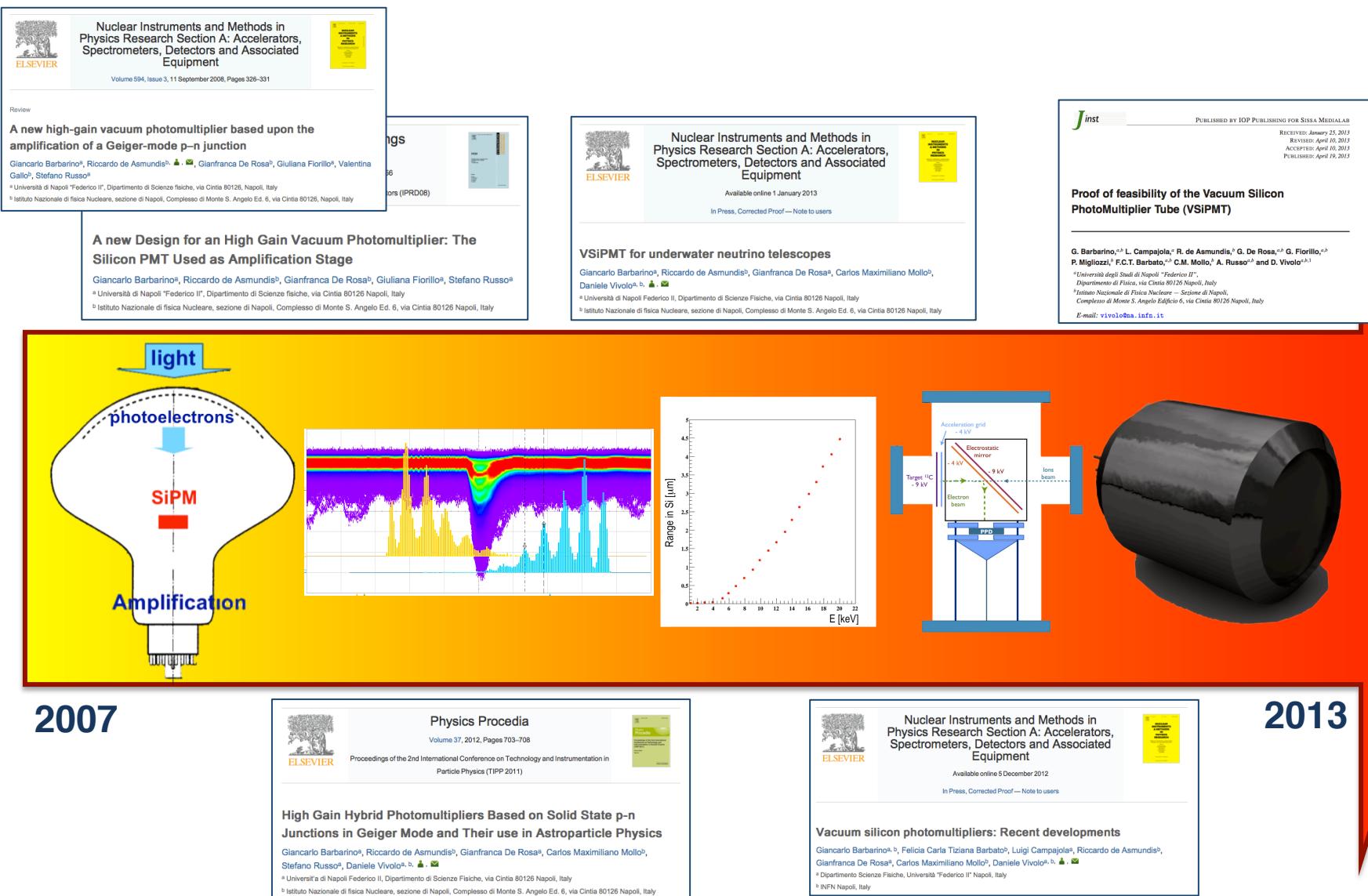
VSiPMT

Unrivalled performances
optimal solution for next
generation DM experiments

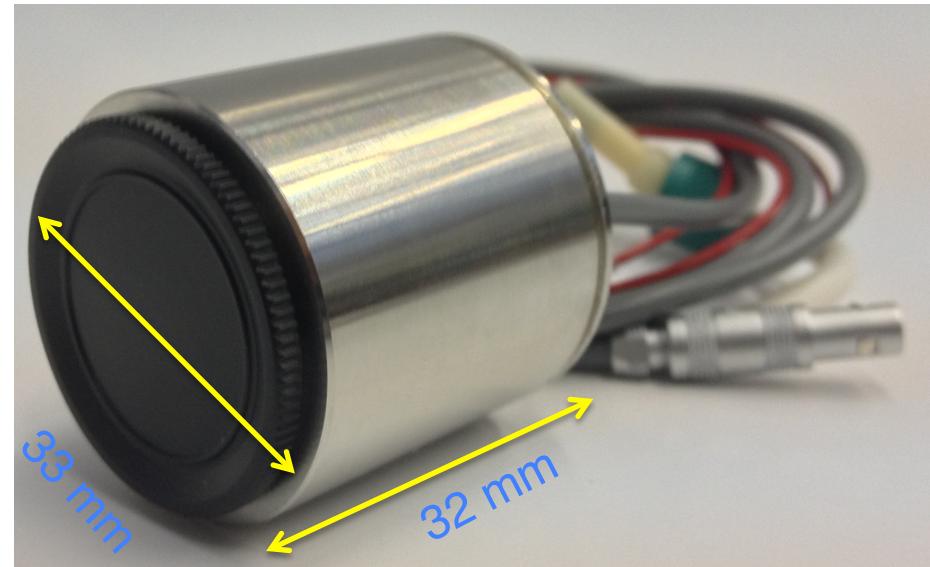
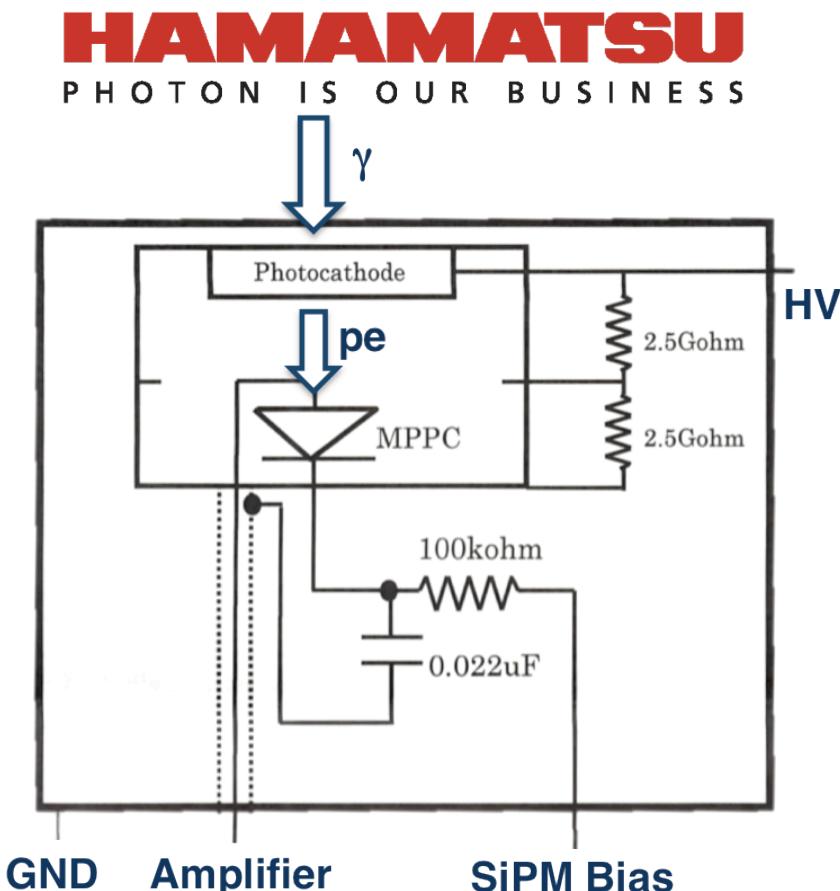
Unprecedented features wrt cryogenic PMTs:

- Photon counting capability;
- Low power consumption;
- Silicon virtually **free of radioactivity** (in addition reduced mass);
- Excellent timing performances (low TTS);
- **High stability (not depending on HV);**
- Excellent SPE resolution.

Timeline



The prototypes

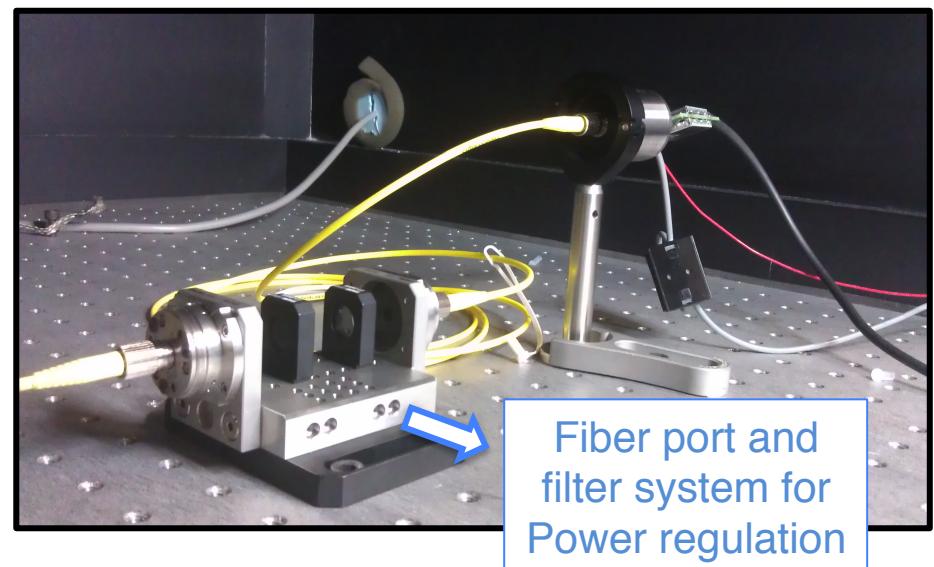
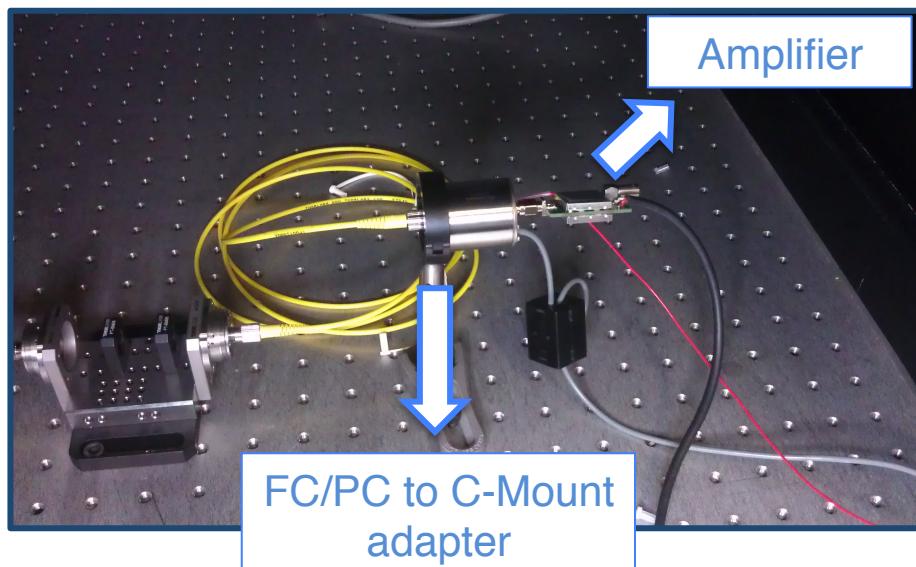
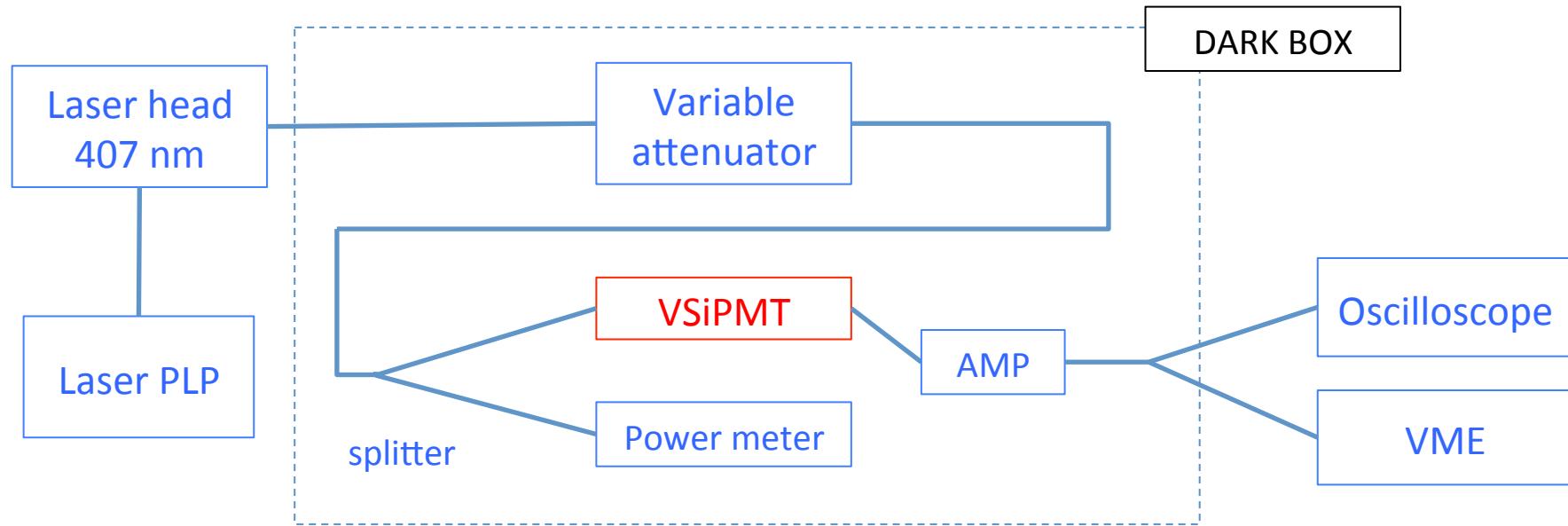


7x7 mm² entrance window
3 mm diameter GaAsP photocathode
2 prototypes:
MPPC 1 mm² / 50 μ m / 400 cells
MPPC 1 mm² / 100 μ m / 100 cells

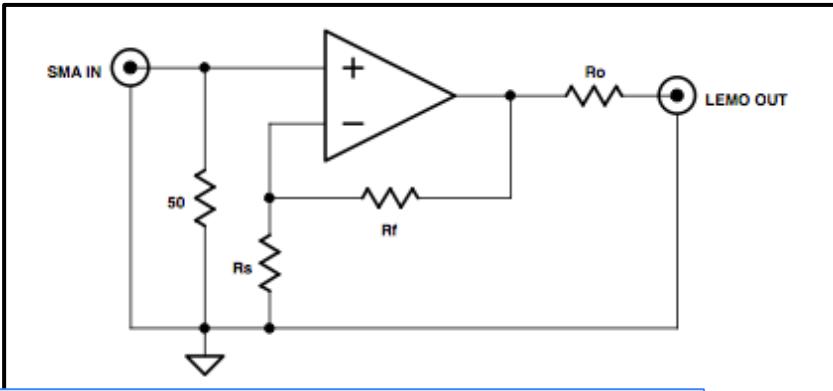
p⁺nvn⁺ configuration, special non-windowed series for ϵ optimization.
Lower voltage required (-2,5/3 kV expected).

No voltage divider: no power dissipation nor complicated circuits to reduce the dissipation
Only a very simple amplifier is required (typ. < 5mW).

Experimental setup



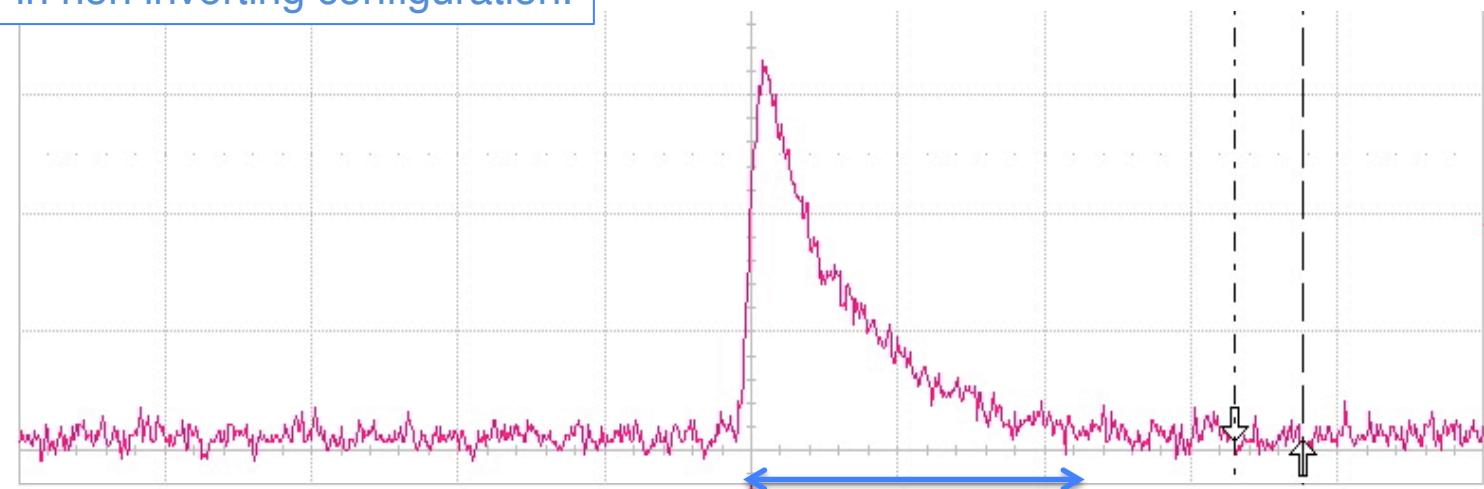
Amplification



Single-state amplifiers based on an OP-AMP in non inverting configuration.



Three different gains: 10, 15, 20.

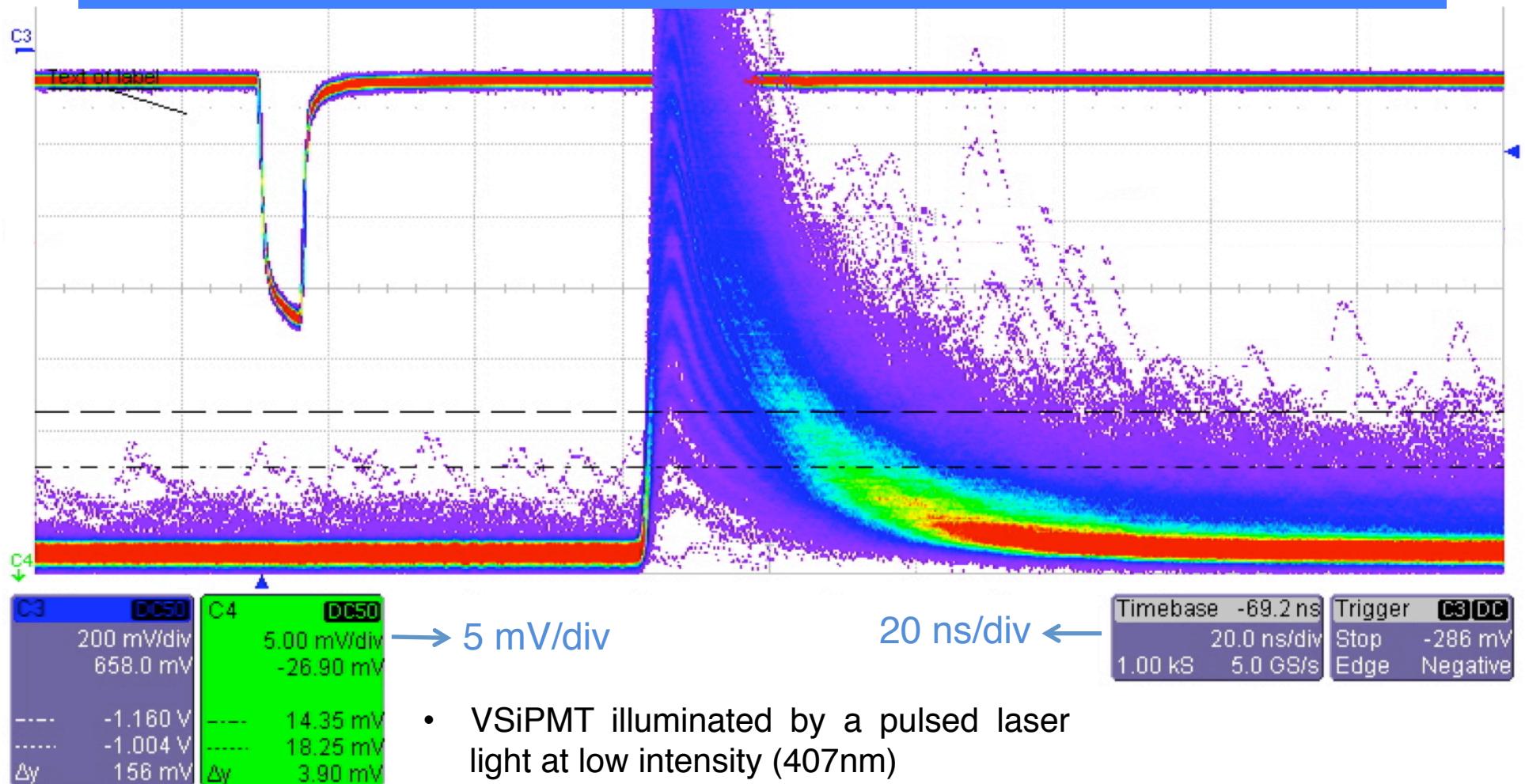


C2 DC50
5.00 mV/div
-5.50 mV
↓ 5.92 mV
↑ 5.82 mV
Δy -100 μV

Power consumption < 5mW

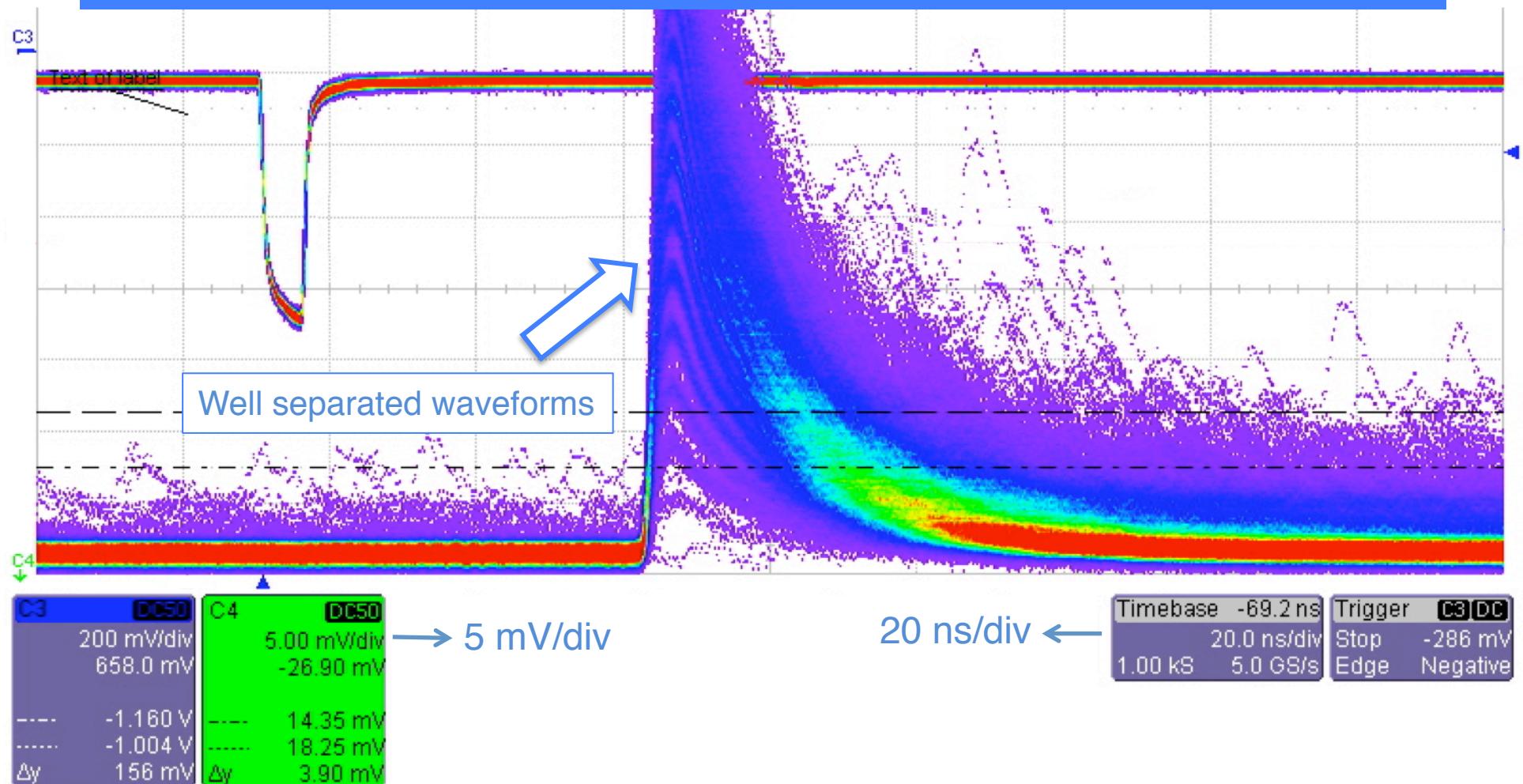
Timebase 0.0 ns
20.0 ns/div
1.00 kS 5.0 GS/s
Trigger C2 DC
Stop 14.95 mV
Edge Positive
X1= 66.0 ns ΔX= 9.4 ns
X2= 75.4 ns 1/ΔX= 106 MHz

Waveforms

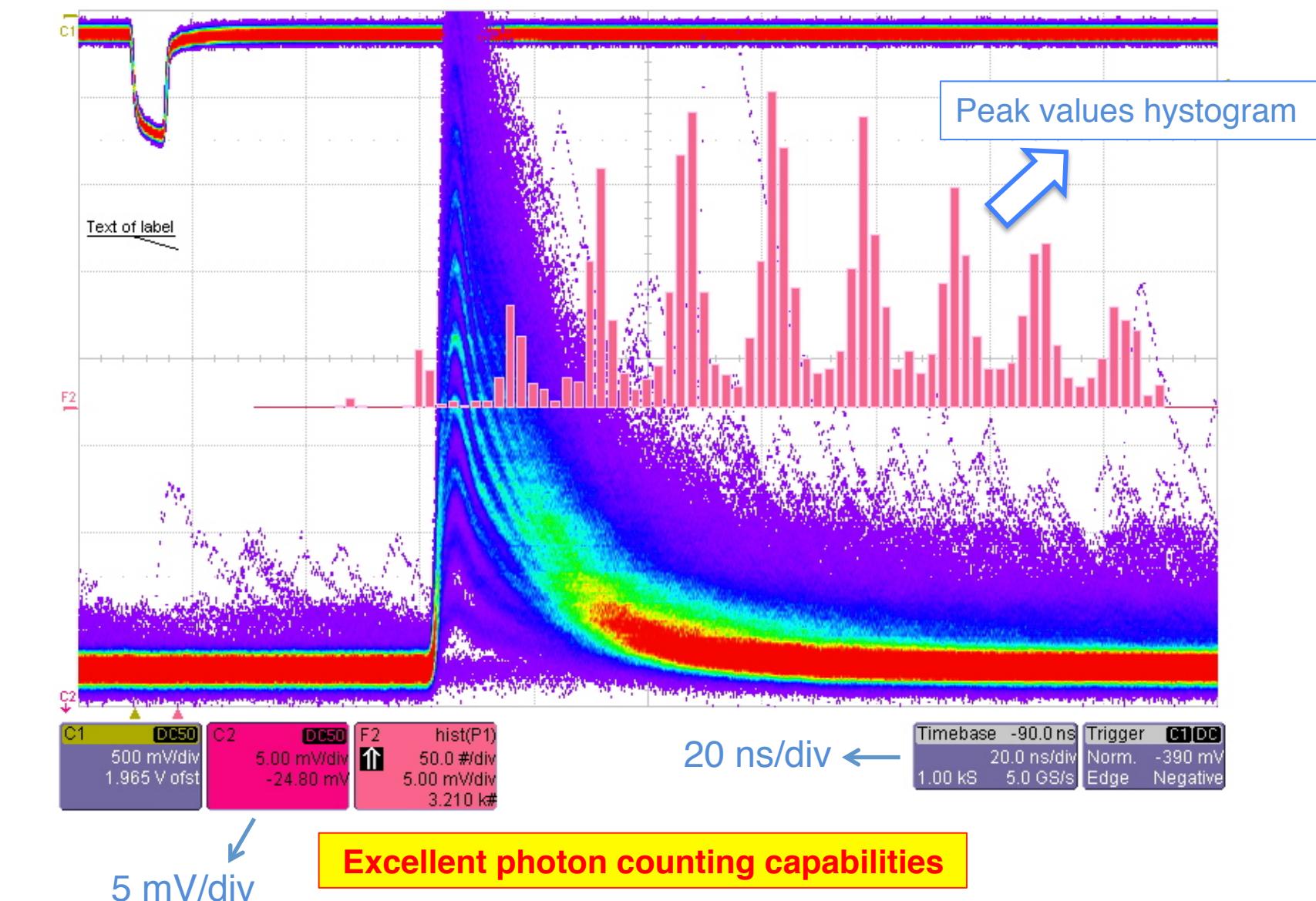


- VSiPMT illuminated by a pulsed laser light at low intensity (407nm)
- oscilloscope triggered in synch with the laser
- Responses for multiple triggers are overlaid

Waveforms



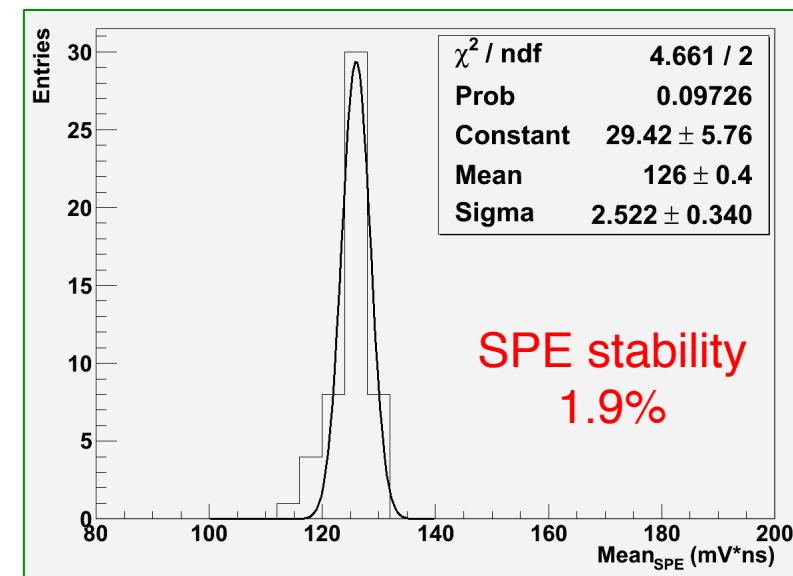
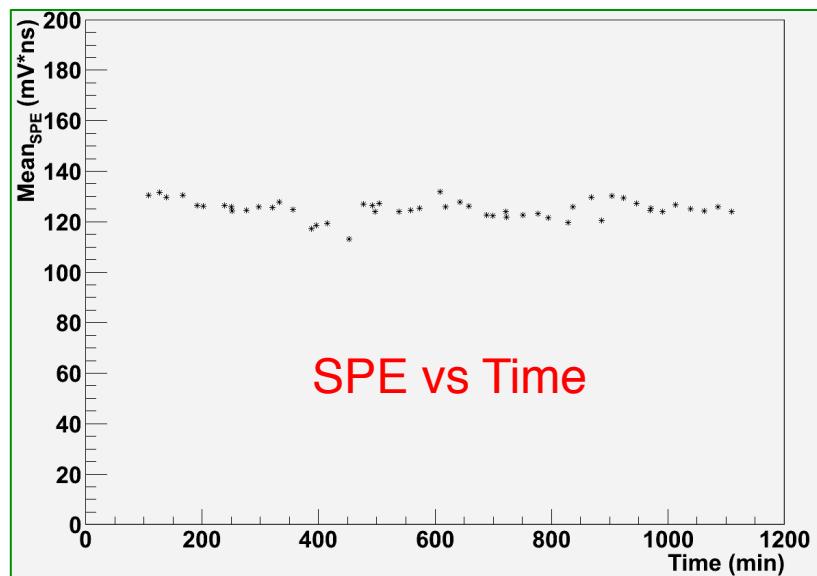
Waveforms



Time stability

100.000 waveforms with low intensity laser light have been acquired every 20 min for 20 hours to study the stability in time of the following parameters:

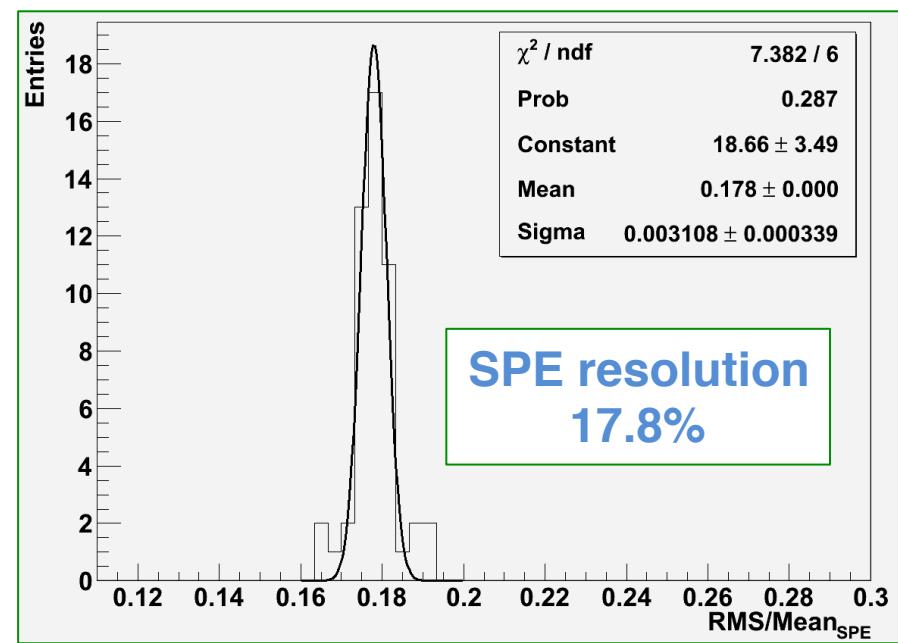
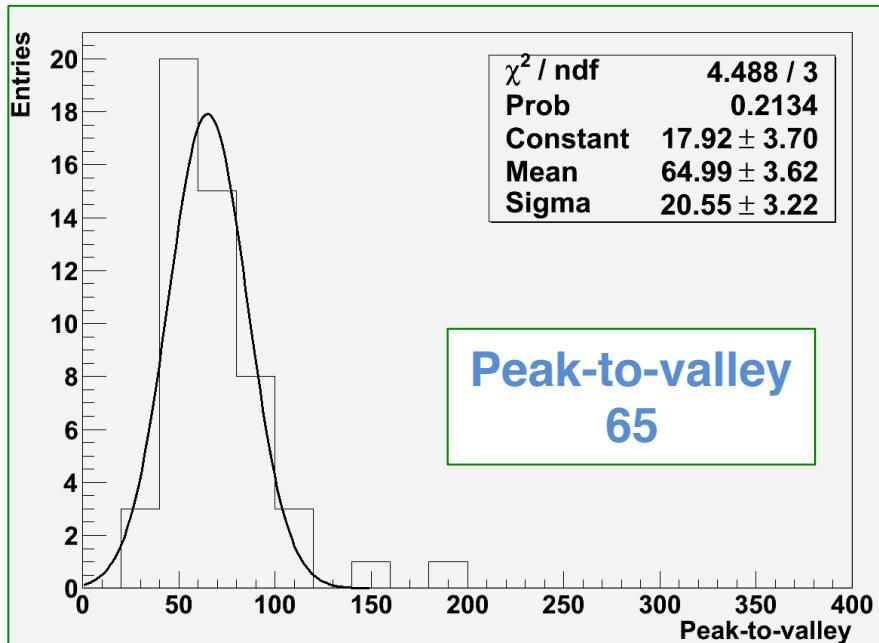
1. Single photo electron response (Mean_{SPE})
2. Resolution of the SPE ($\text{RMS}_{\text{SPE}}/\text{Mean}_{\text{SPE}}$)
3. Peak-to-Valley ratio



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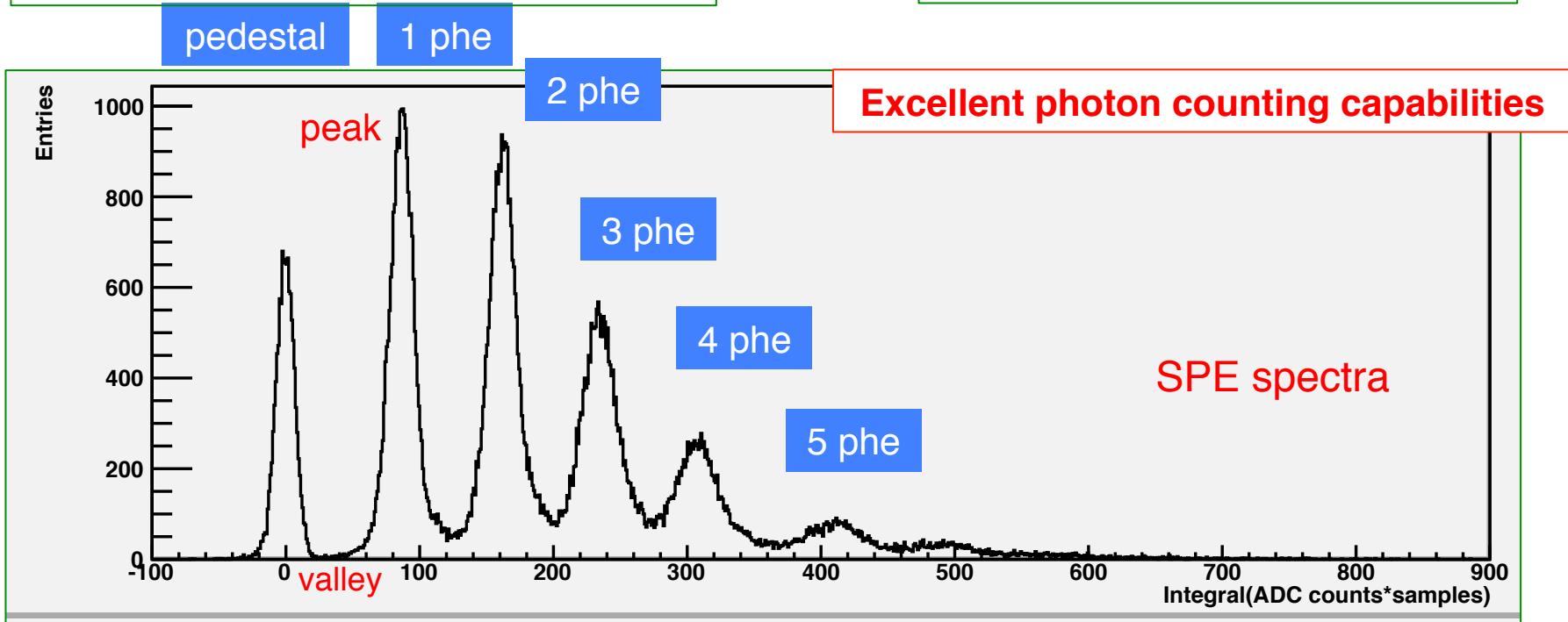
SPE spectra

100.000 waveforms for each acquisition run with low laser intensity.

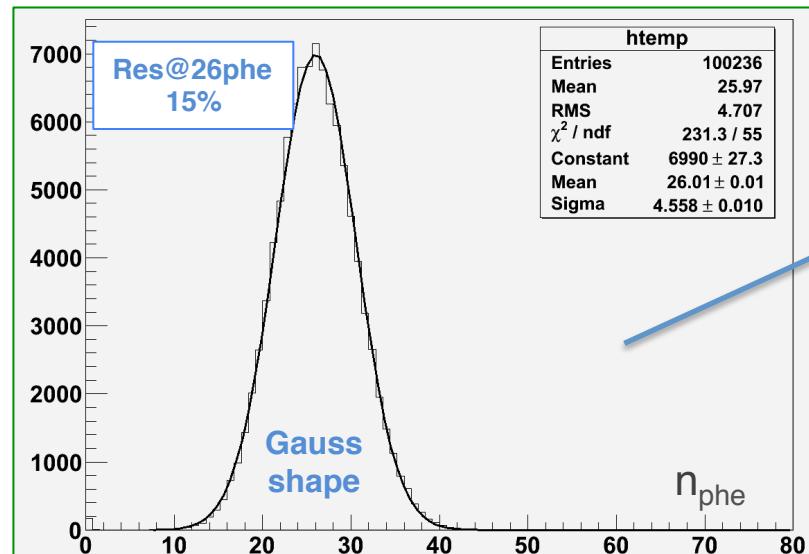
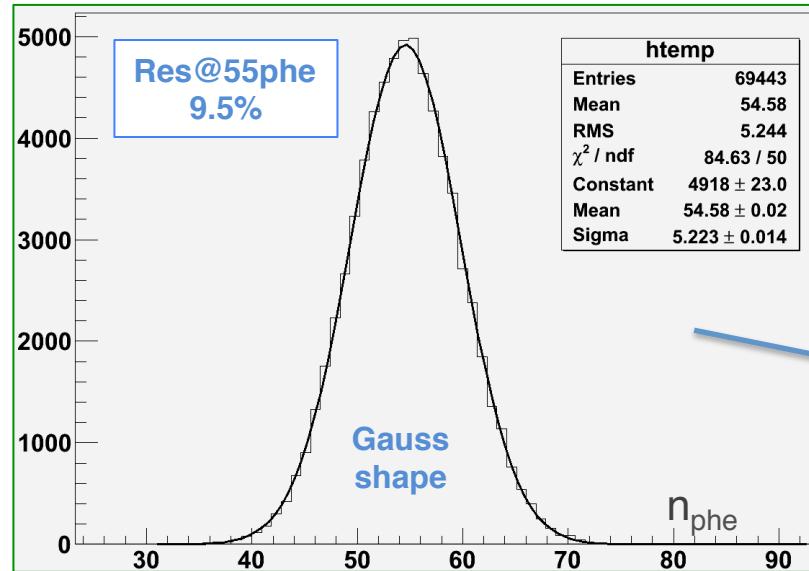
Integral of the waveform in a window of 100 ns after subtracting the baseline.

DAQ ADC CAEN V1720E
12 bit – 4 ns sampling
Laser TRG 10kHz

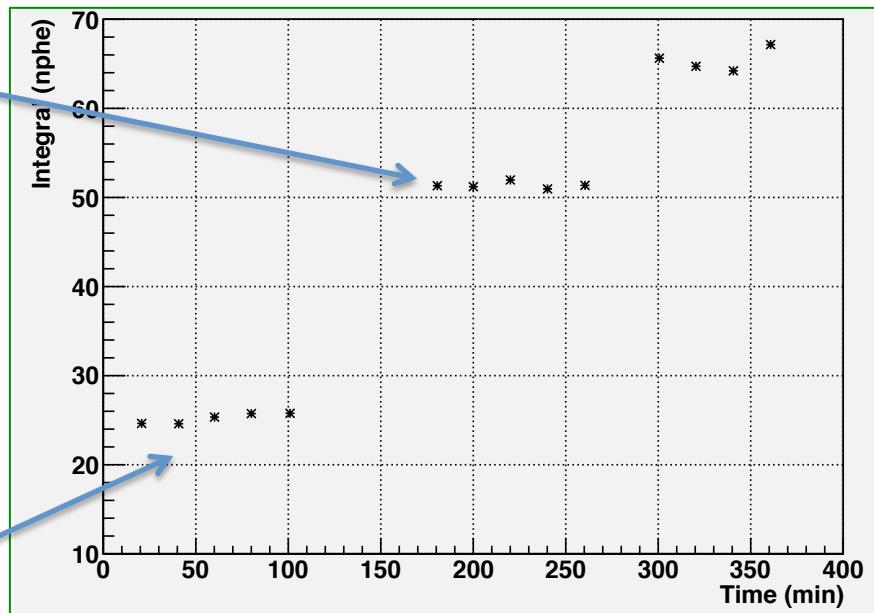
VSiPMT working point
 $V_{bias} = 72.5 \text{ V} - HV = 4 \text{ kV}$
Amplification x20



Multi photon response and stability

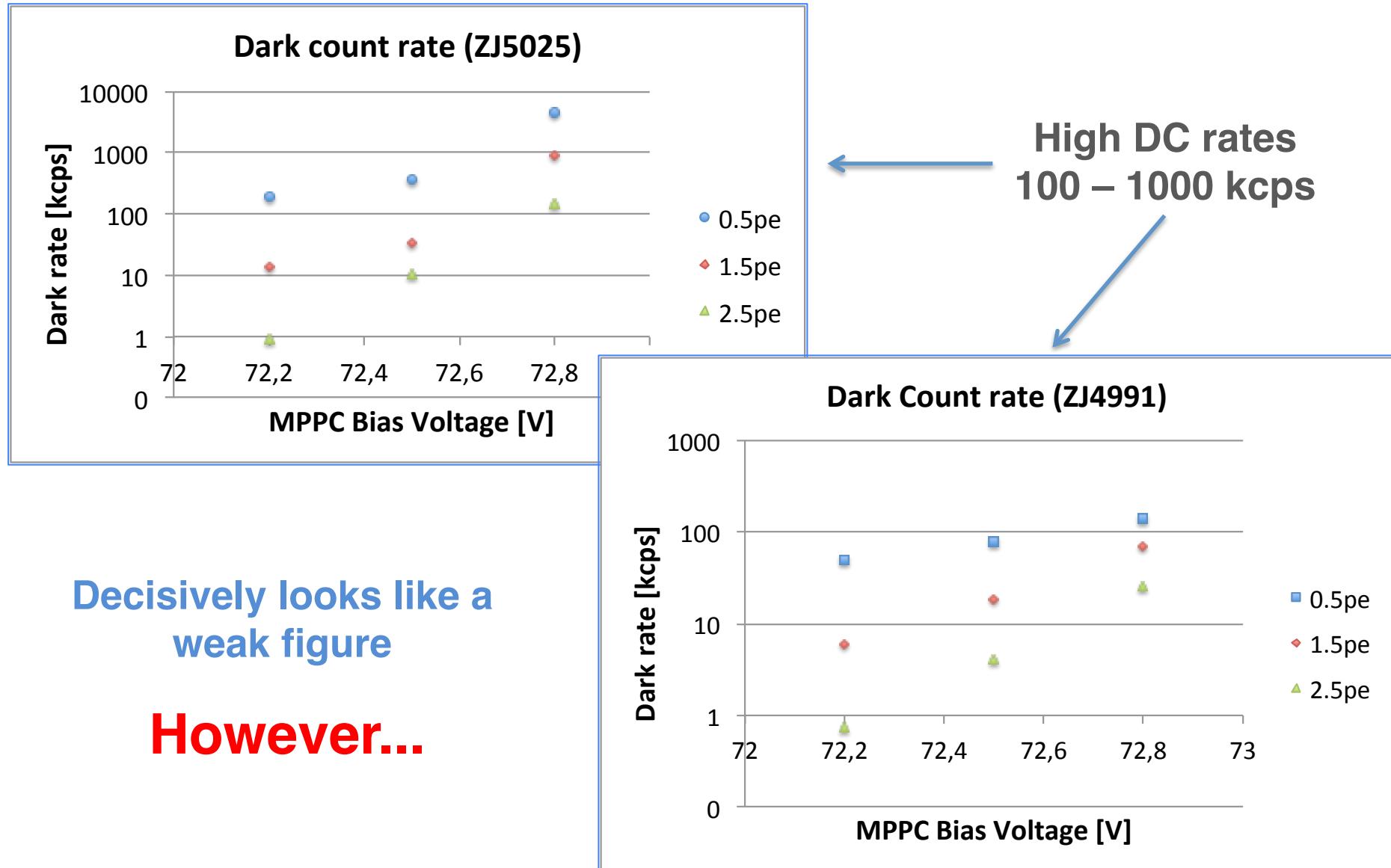


NO drop in the MPE response on 100 min



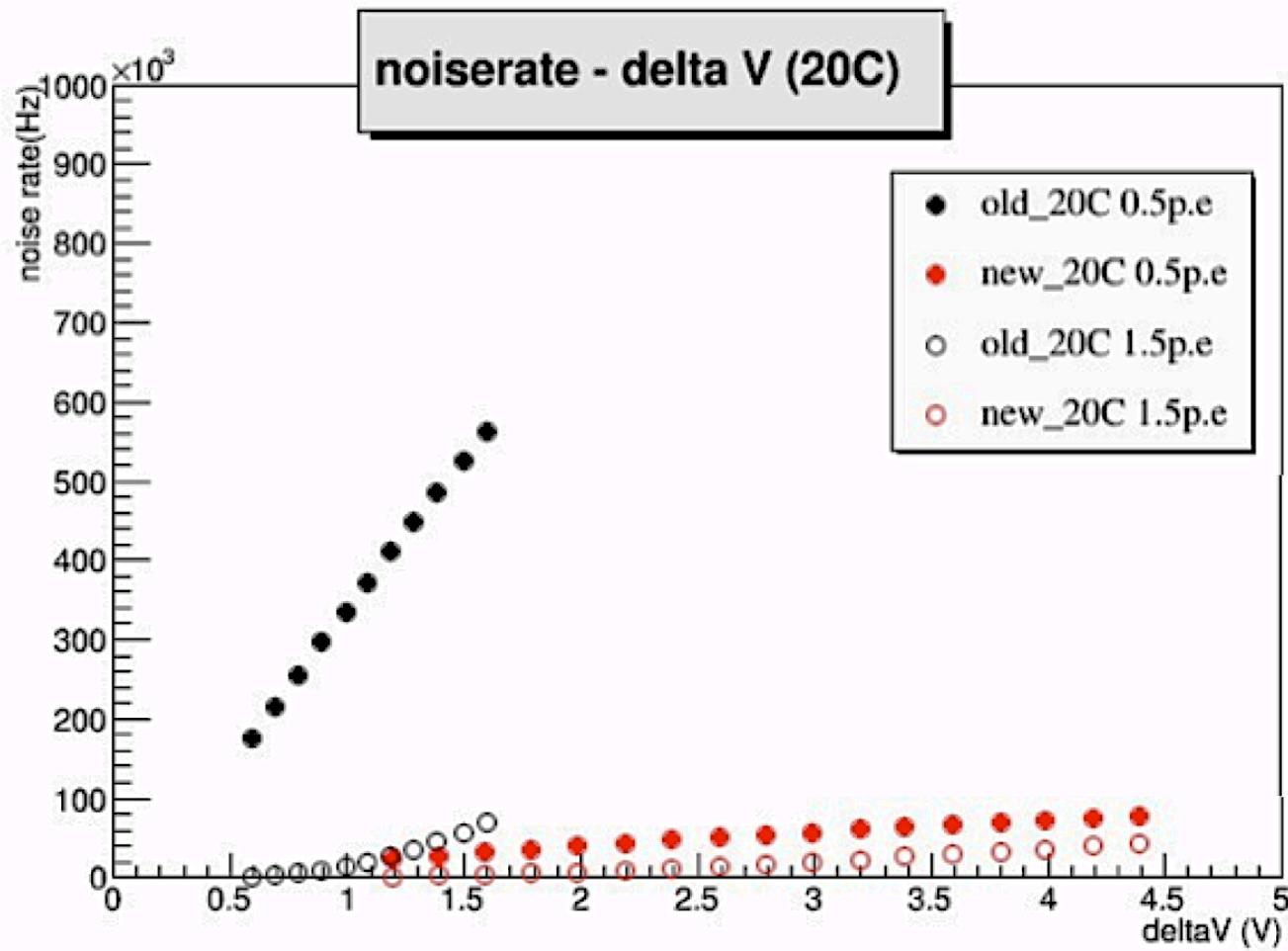
NO fatigue effect on high illumination

Dark counts/1



Dark counts/2

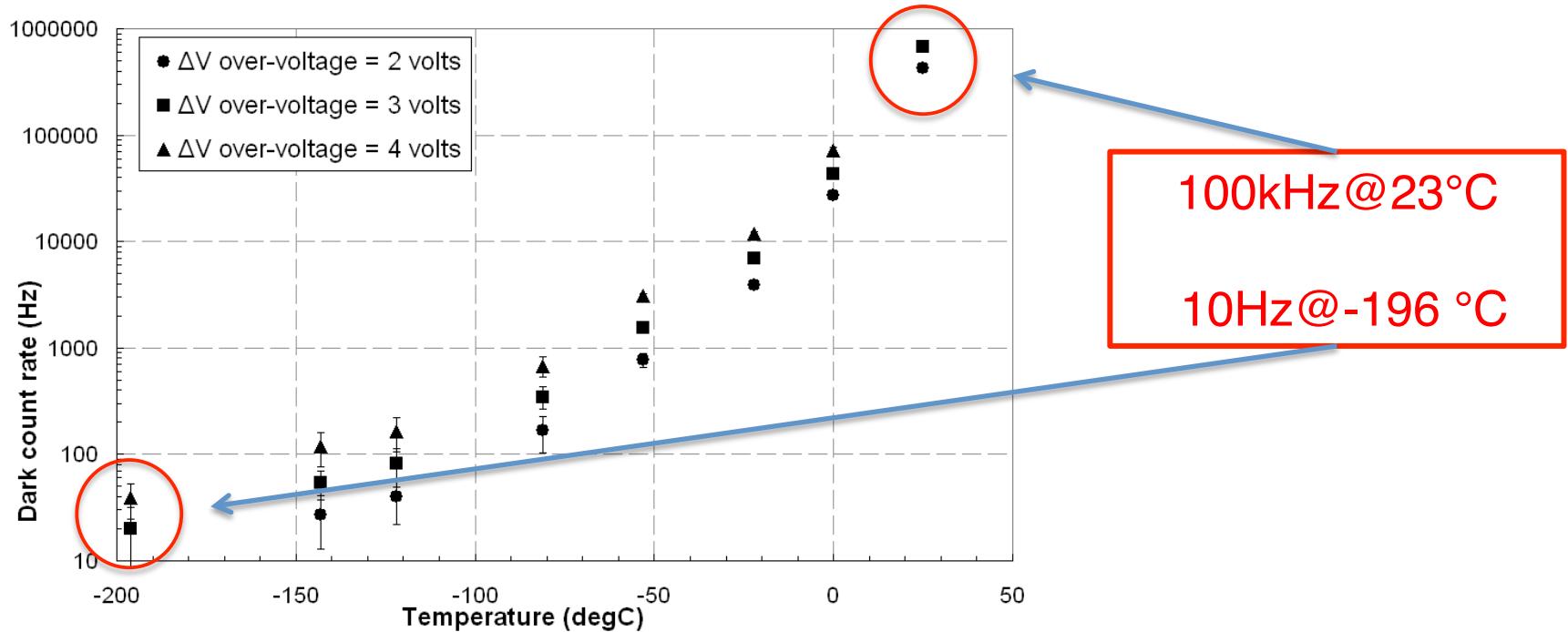
New generation Hamamatsu MPPCs



Advantages at low temperature

Cryogenic application would reduce drastically the dark rate

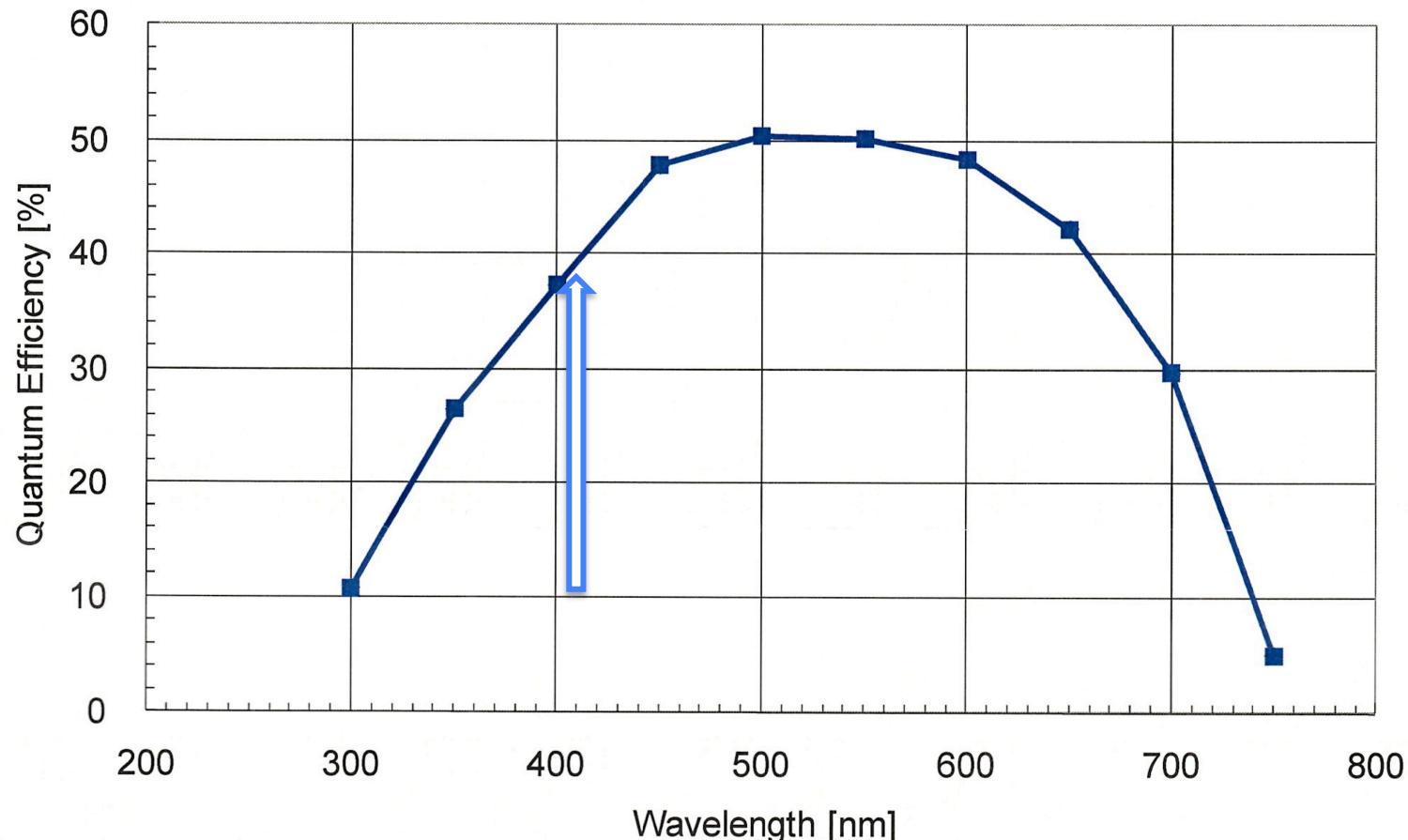
P.K. Lightfoot, Characterization of a silicon photomultiplier device for applications in liquid argon based neutrino physics and dark matter searches, JINST 3 P10001, 2008.



Efficiency

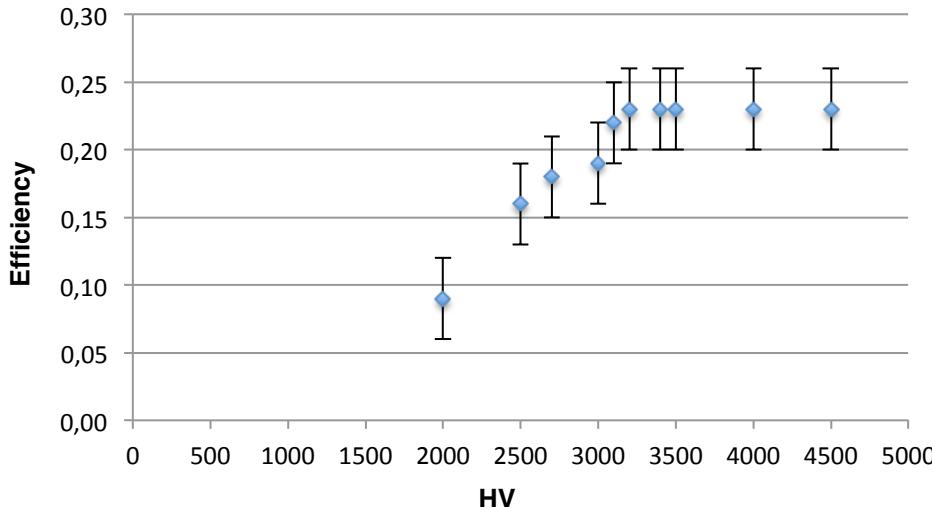
Photocathode Spectral Response

(Photocathode applied voltage: 90V)



Efficiency

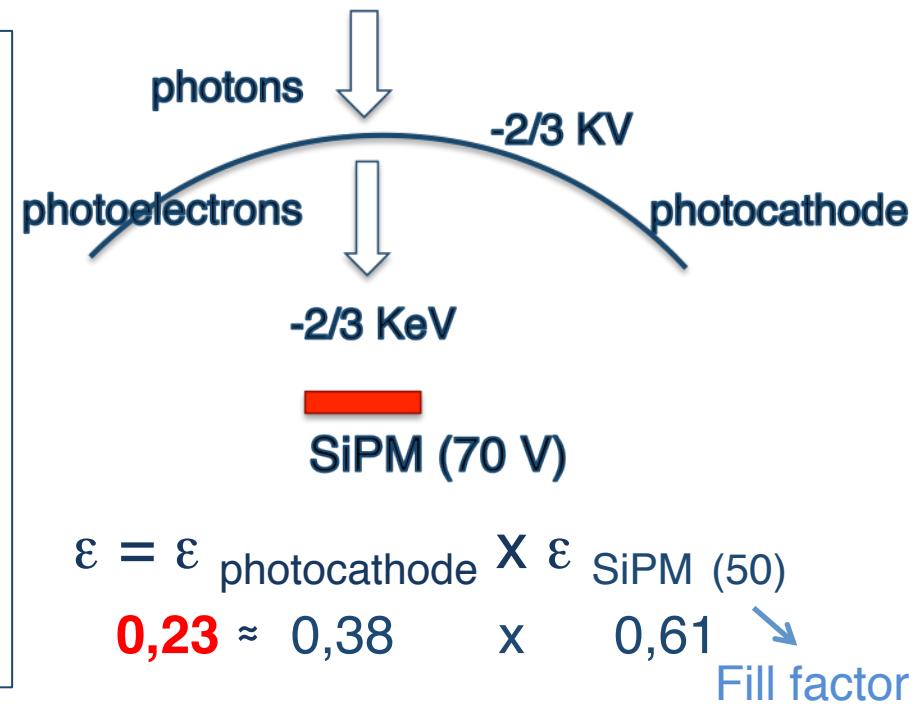
VSiPMT (ZJ5025) Operating point



VSiPMT (ZJ5025)
measured efficiency
 $\epsilon = 0.23$

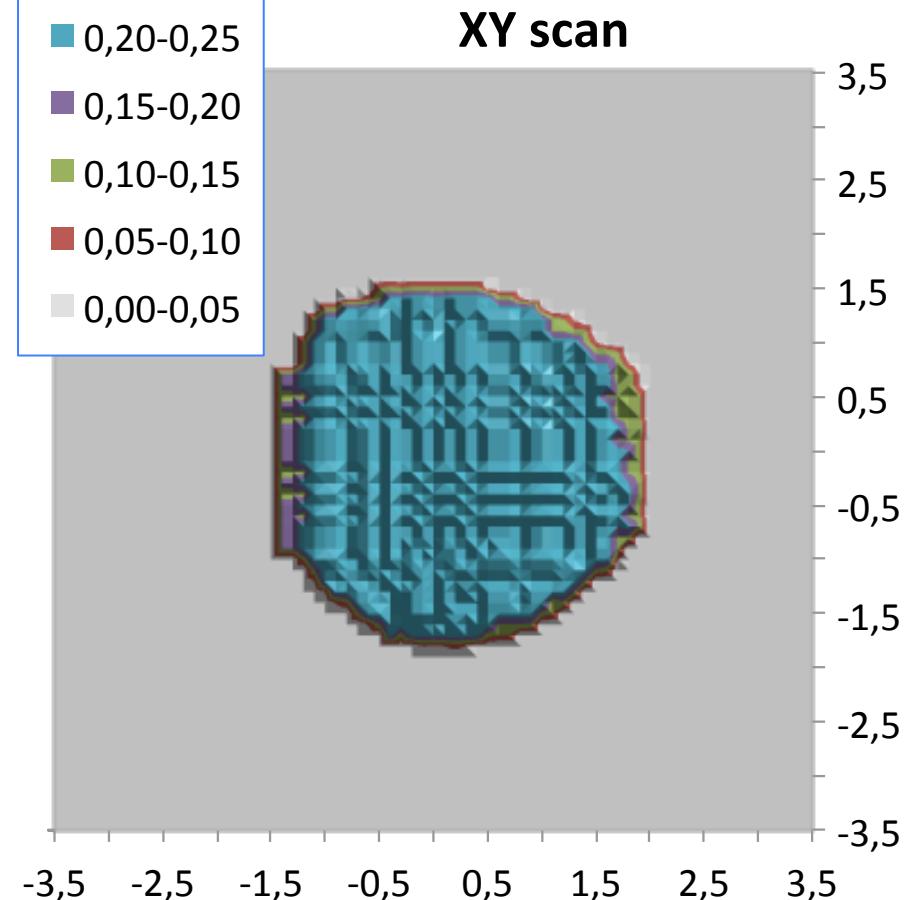
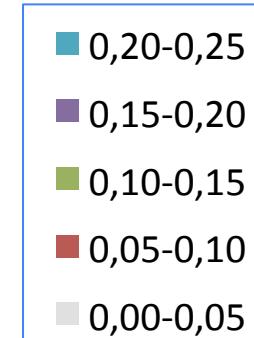
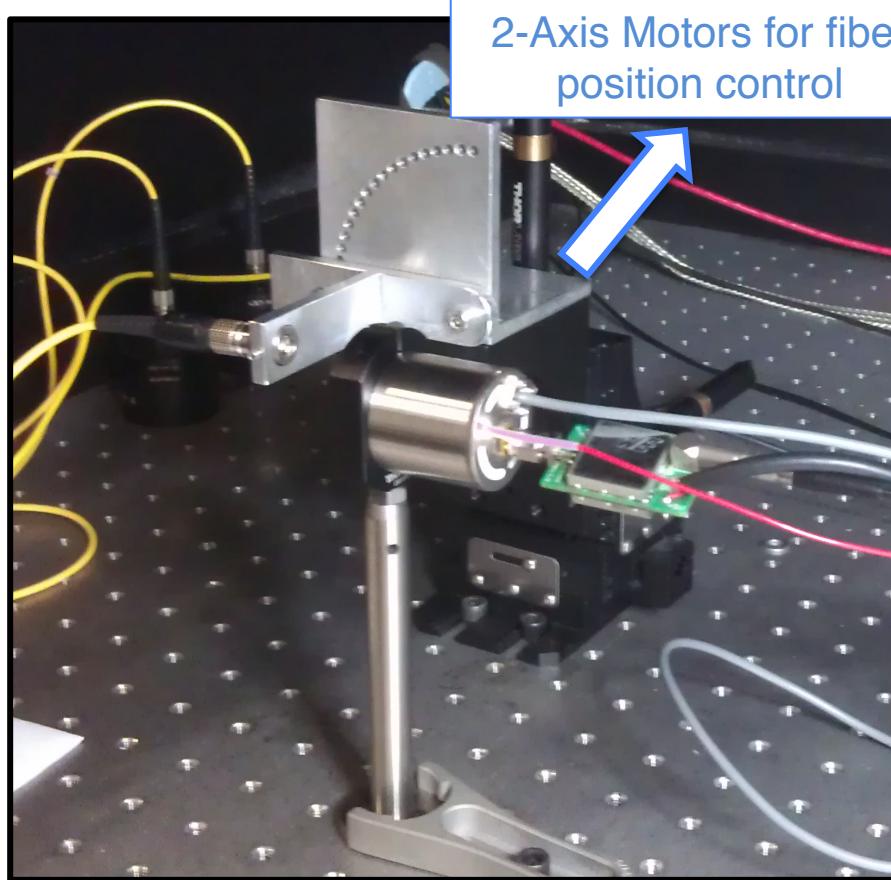
in agreement with
expectations

**Efficiency is highly stable over 3200 V.
No need for high voltage stabilization.**

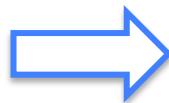


- Reducing the SiO_2 coating layer it will be possible to reach the plateau region at even lower voltages.
- The HV implies NO power consumption (NULL current) unlike PMTs. Moreover, for PMTs the power consumption increases with the rate!

XY scan

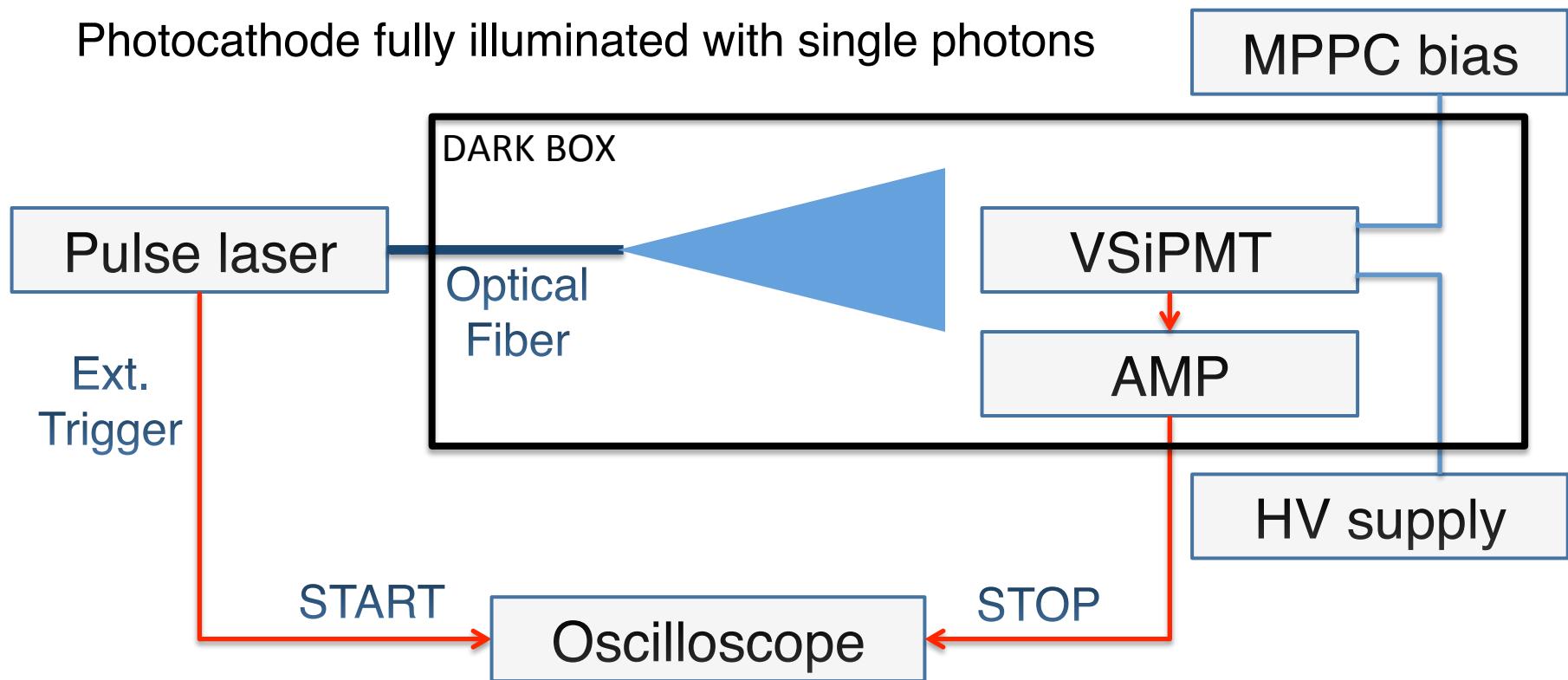


Homogeneous efficiency
≈ 0.2 over a 7mm² surface



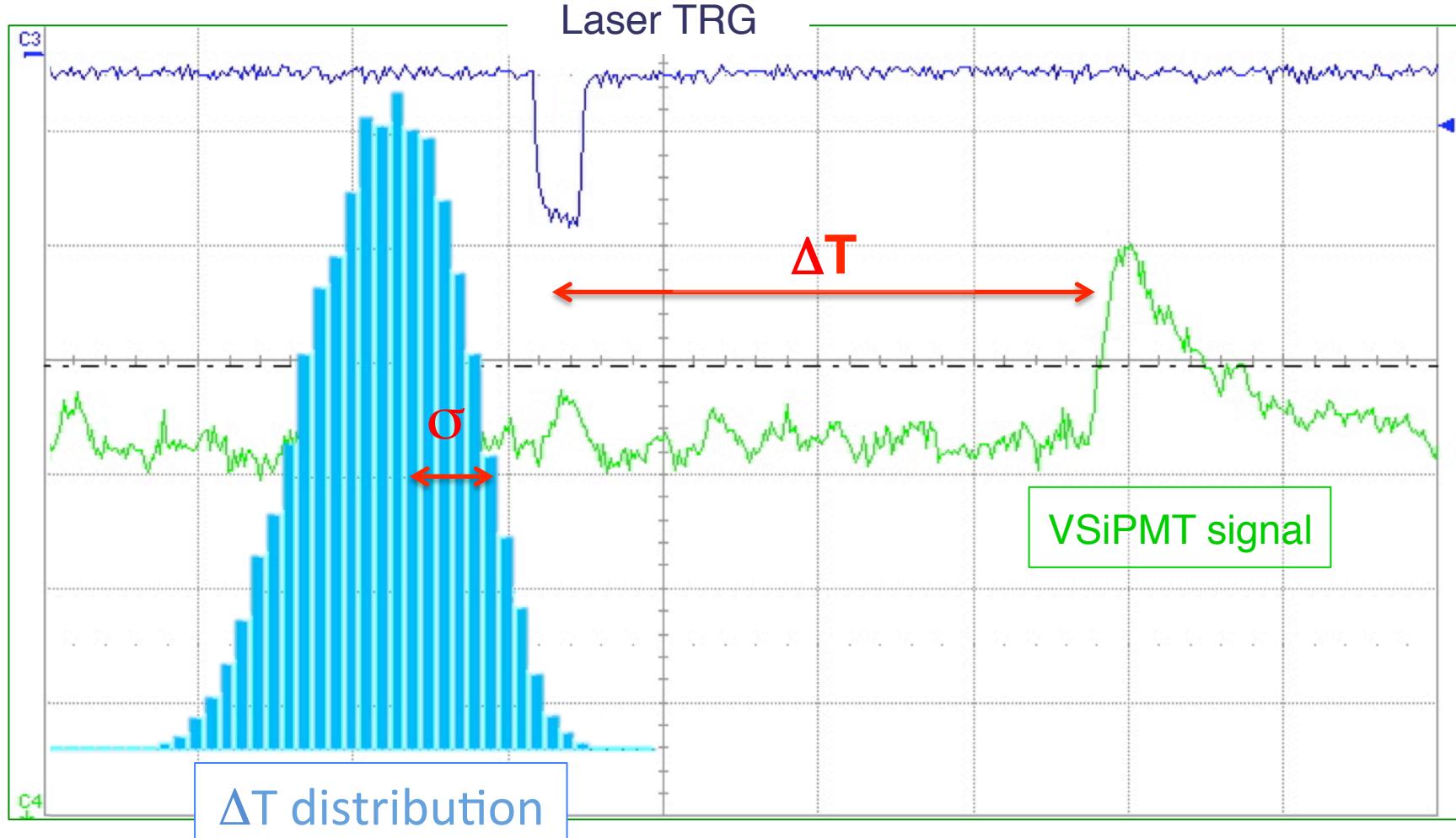
Surface increase factor ≈ 7

TTS



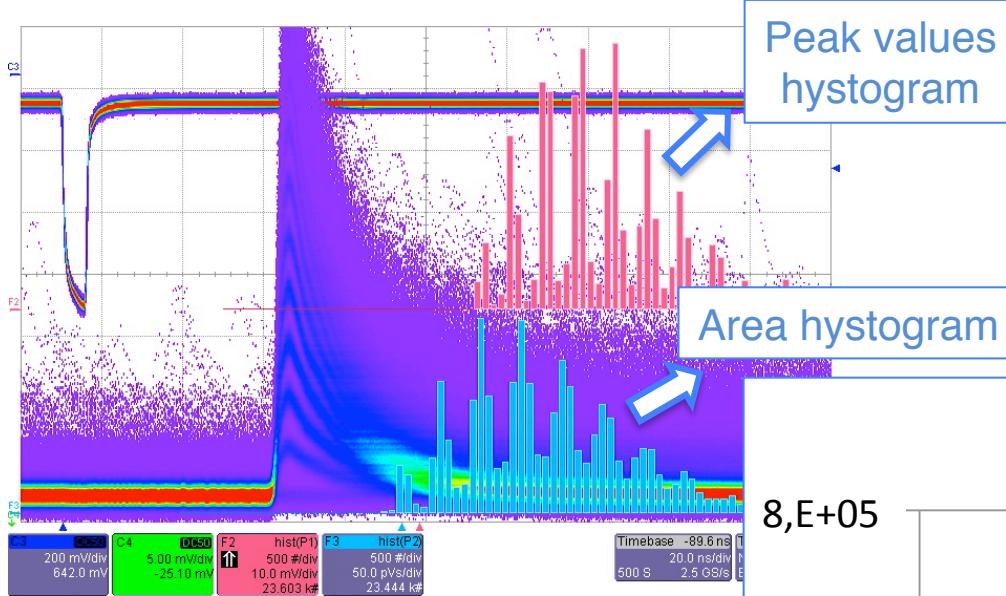
- The output from the VSiPMT is fed as the stop signal via a discriminator;
- We measure the time interval between the "start" and "stop" signals.

Transit Time Spread



VSiPMT
TTS (sigma) < 0.5 ns

Gain



Measure of the charge corresponding to 1 pe (peaks in area histogram)

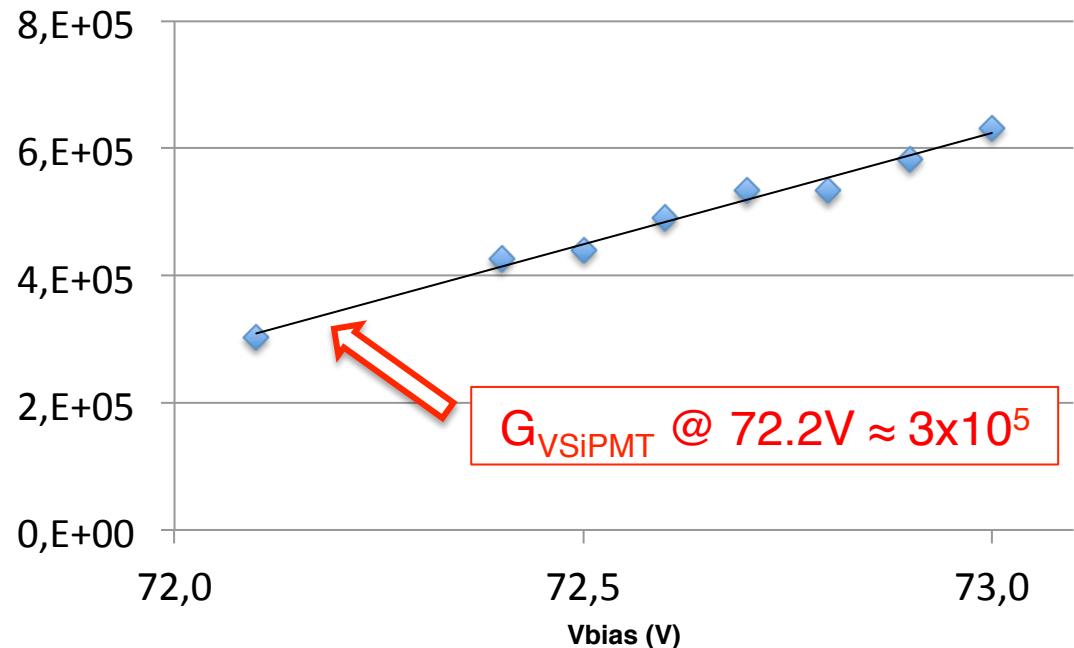
High gain (10^5 – 10^6), linear trend

$$\text{Total Gain} = G_{\text{VSiPMT}} \times G_{\text{AMP}}$$

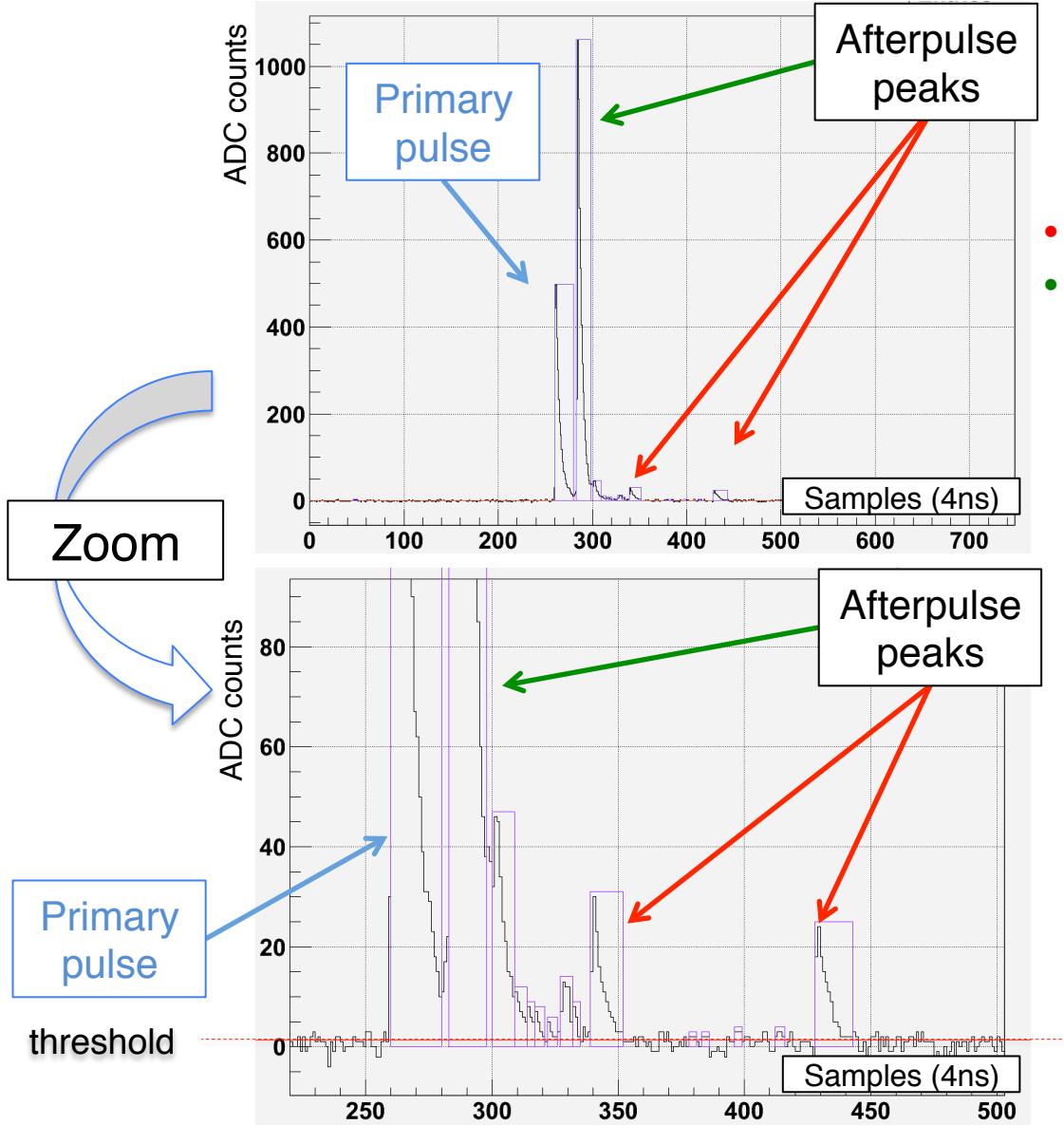
Ideal Working Point: 72.2V

- $G \approx 6 \times 10^6$ ($G_{\text{AMP}} = 20$);
- Dark Count ≈ 60 kcps;
- TTS < 0.5 ns.

VSiPMT (ZJ5025) Gain



Afterpulses



2 Afterpulse classes:

- SiPM afterpulses (1-3 pe, $\approx 10\%$)
- “Vacuum” afterpulses (gas residuals contribution, high intensity, $\approx 0.02\%$)

Peak finder:

Searches for peaks above 3 RMS of the noise level distribution

For each peak we reconstruct:

Arrival time
Integral
Pulse height

Afterpulse rate

$$R_{AP} = \frac{\sum I_{AP}}{\sum I_{MP}}$$

R_{AP} : afterpulse rate;

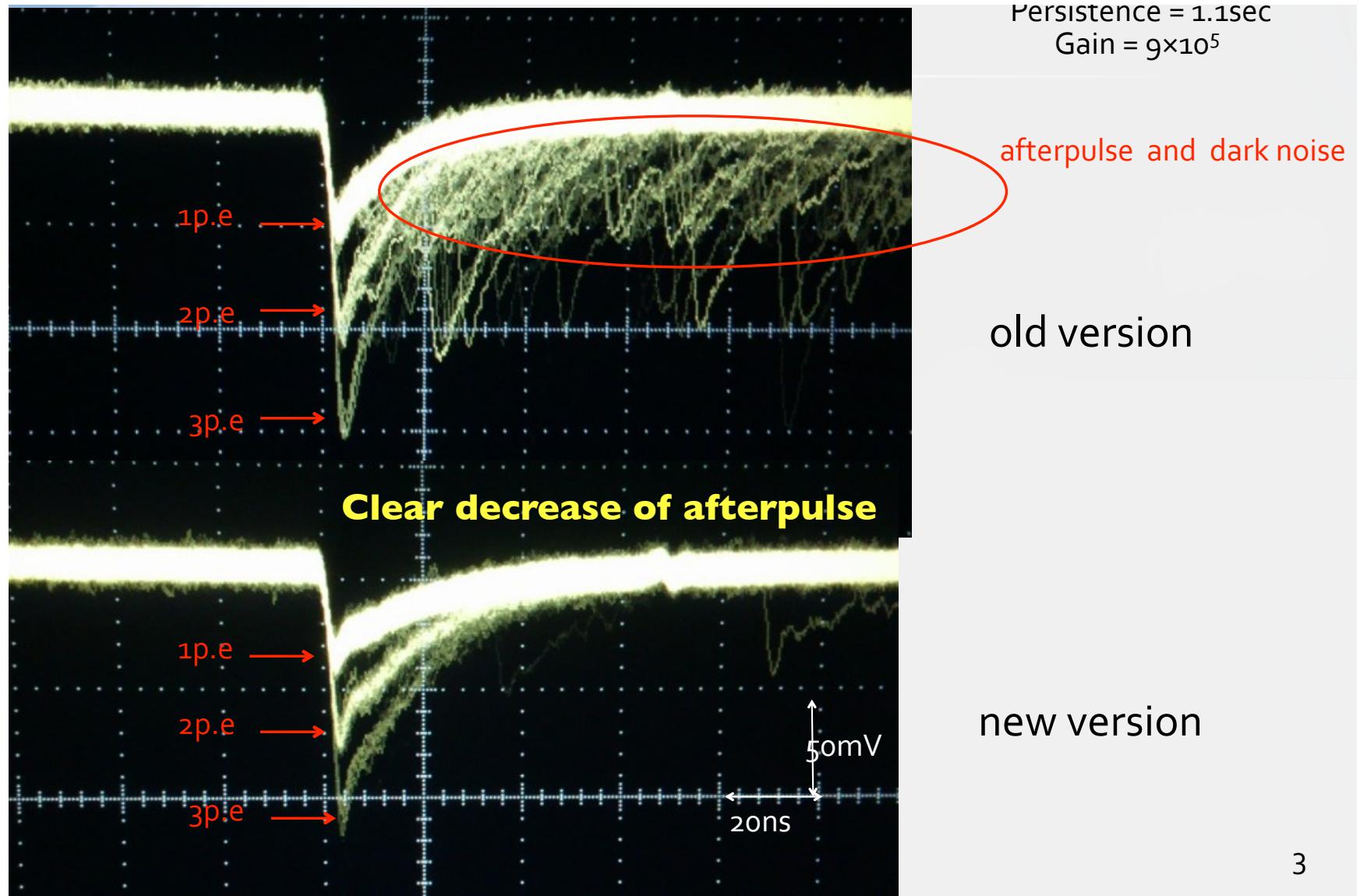
I_{AP} : sum of the intensities of each afterpulse peak found in 100.000 waveforms;

I_{MP} : sum of the intensities of the primary pulses of 100.000 waveforms;

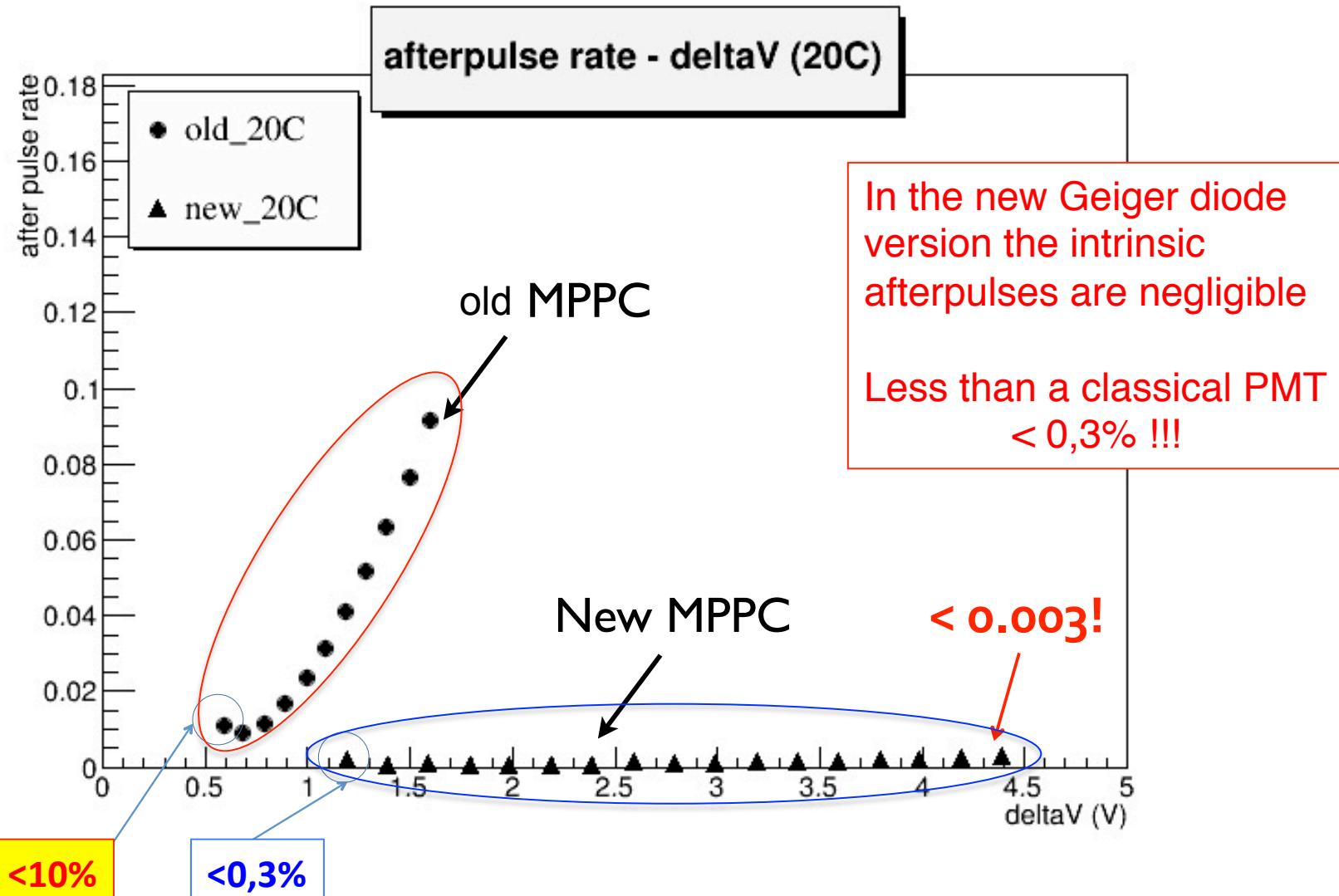
Afterpulse rate Table summary

Threshold (pe)	Afterpulse rate
>0.50	10.41%
>0.75	9.40%
>1.00	7.34%
>2.00	2.38%
>5.00	0.23%
>10.00	0.02%

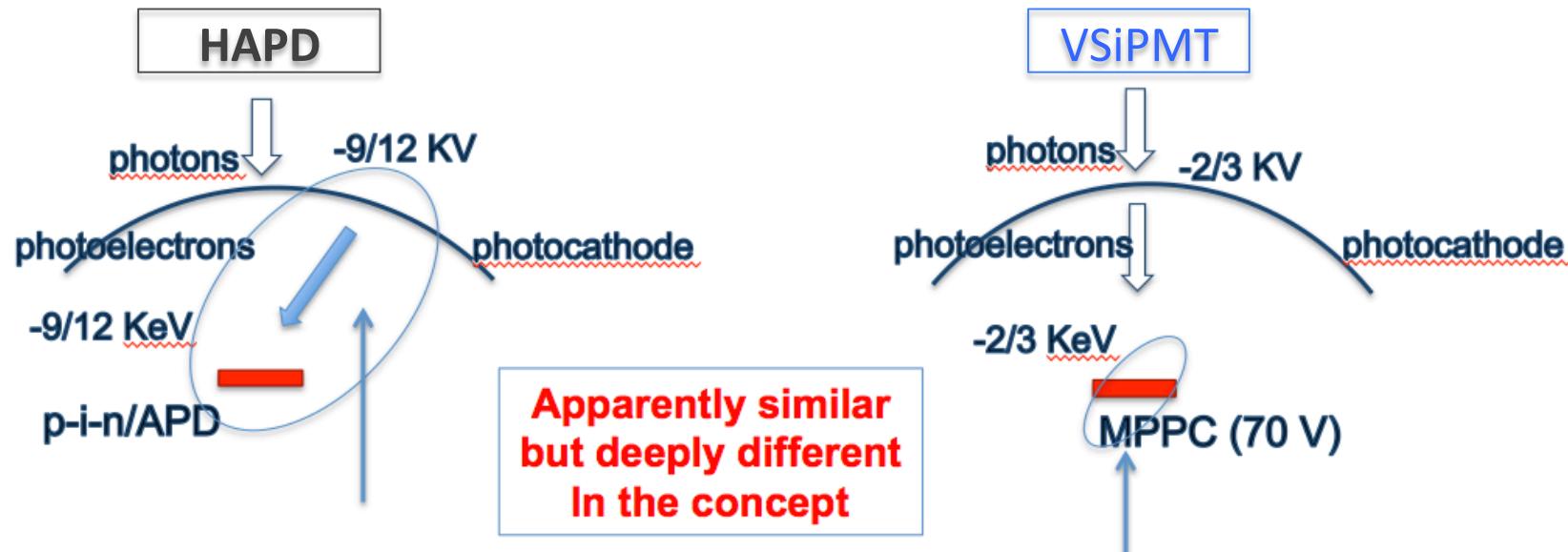
Afterpulse rate



Afterpulse rate



VSiPMT vs HAPD



Need of HV to obtain a high gain

High gain obtained with low voltage in the SiPM

Drawbacks of the APD solution

- $G = E_{phe}/E_{e,h} \approx 10^4 - 10^5$
- too low Gain. HV gain required
- G depending on HV
- Need a strong HV critical stabilization.
- Difficult and expensive insulation

Advantages in the VSiPMT solution

- $G > 10^6$: a factor 10 higher.
- Low HV, **no need for bombardment gain** only energy for photoelectron transfer
- **Low voltage Gain: easy to stabilize**
- Normal insulation

VSIPMT VS PMT

	PMT	VSiPMT	comparison
Efficiency	Photocathode x 1 st dynode	Photocathode x Fill factor MPPC ($\rightarrow 1$)	\approx comparable (slightly worse)
Gain	$10^5 - 10^6$	$10^5 - 10^6$	\approx equivalent
Timing	nsec	fractions of nsec (no spread dynodes)	+ VSiPMT
Power Consumption	Divider Dissipation	No dissipation: just amp. G=10-20 (<5mW)	+VSiPMT
Stability H.V.	H.V. stabilization for stable gain	No H.V. stability (plateau)	+VSiPMT
Dark counts	\approx kHz @ 0.5pe	VLT $\rightarrow \approx$ 10Hz	+VSiPMT
Photon counting	difficult	excellent	+VSiPMT
Peak-to-valley ratio	≈ 3 (typ.)	> 60	+VSiPMT
Afterpulse (@0.5pe)	$\approx 10\%$	Next gen. MPPC <0.3%	+VSiPMT
SPE resolution	$\approx 30\%$ (typ.)	$\approx 17.8\%$	+VSiPMT

Conclusions and Perspectives

VSiPMT is an innovative design for a modern hybrid photodetector based on the combination of a Silicon PhotoMultiplier (SiPM) with a Vacuum PMT standard envelope

It has many **UNPRECEDENTED** features, such as:

- Photon counting capability;
- Low power consumption;
- Excellent timing performances (low TTS);
- Virtually **free of radioactivity**;
- Excellent SPE resolution;
- High stability (not depending on HV).

making it a very attractive solution for next generation DM experiments

STILL IMPROVABLE!!

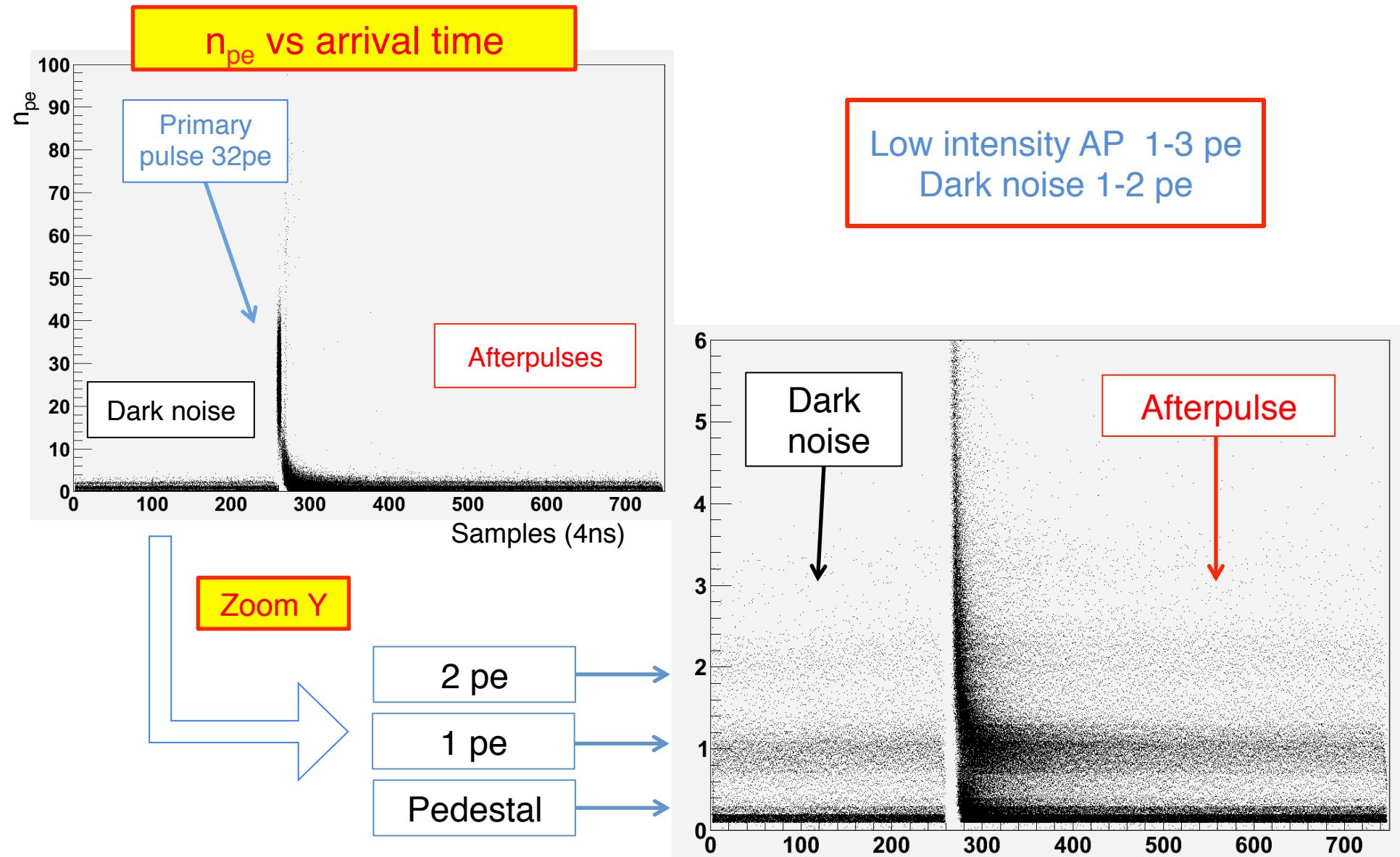
New generation of Hamamatsu MPPCs:

- sensibly lower afterpulse rates;
- lower noise: much reduced dark counts;
- higher gain → no amplification required (persp.), even lower power consumption

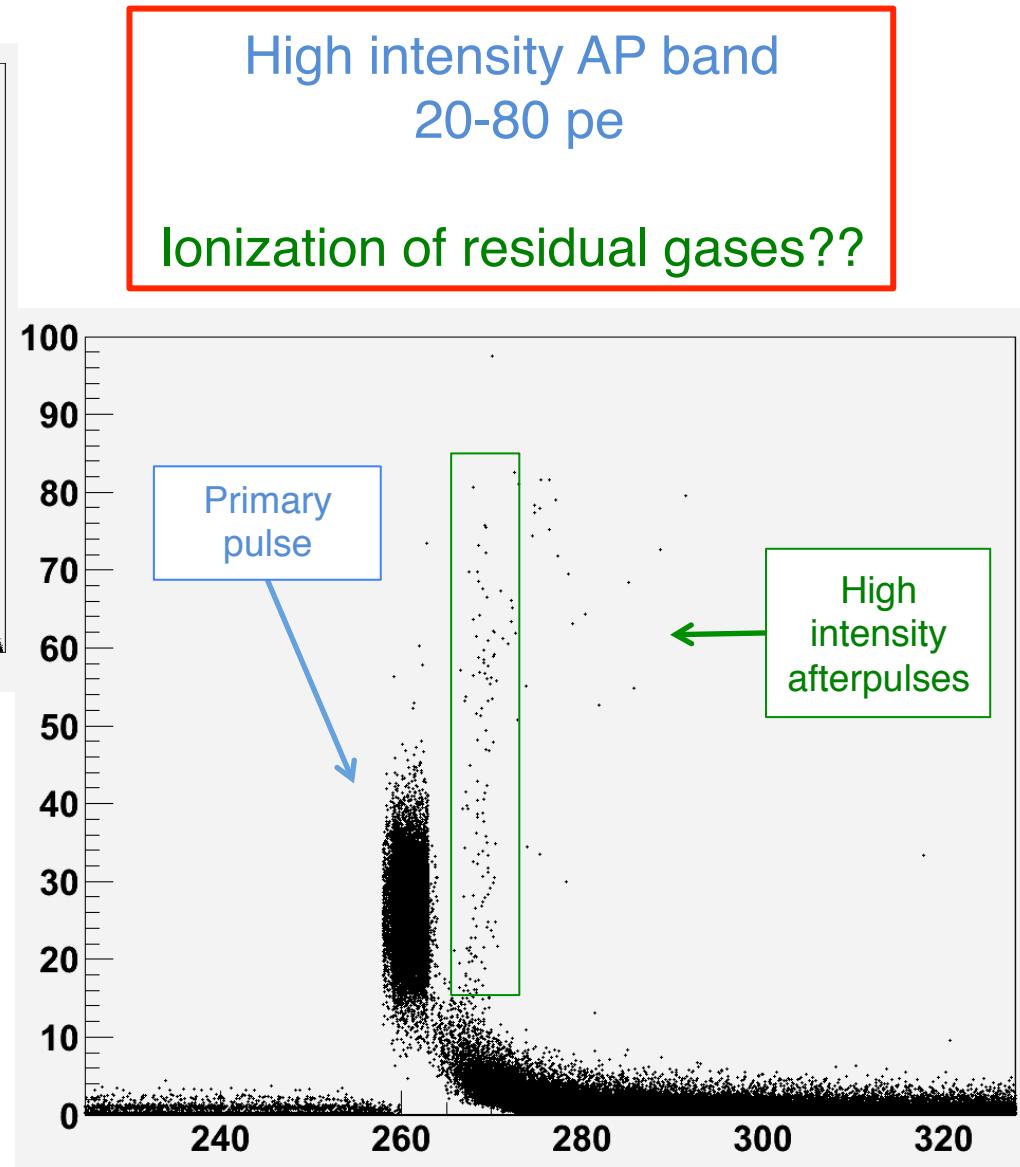
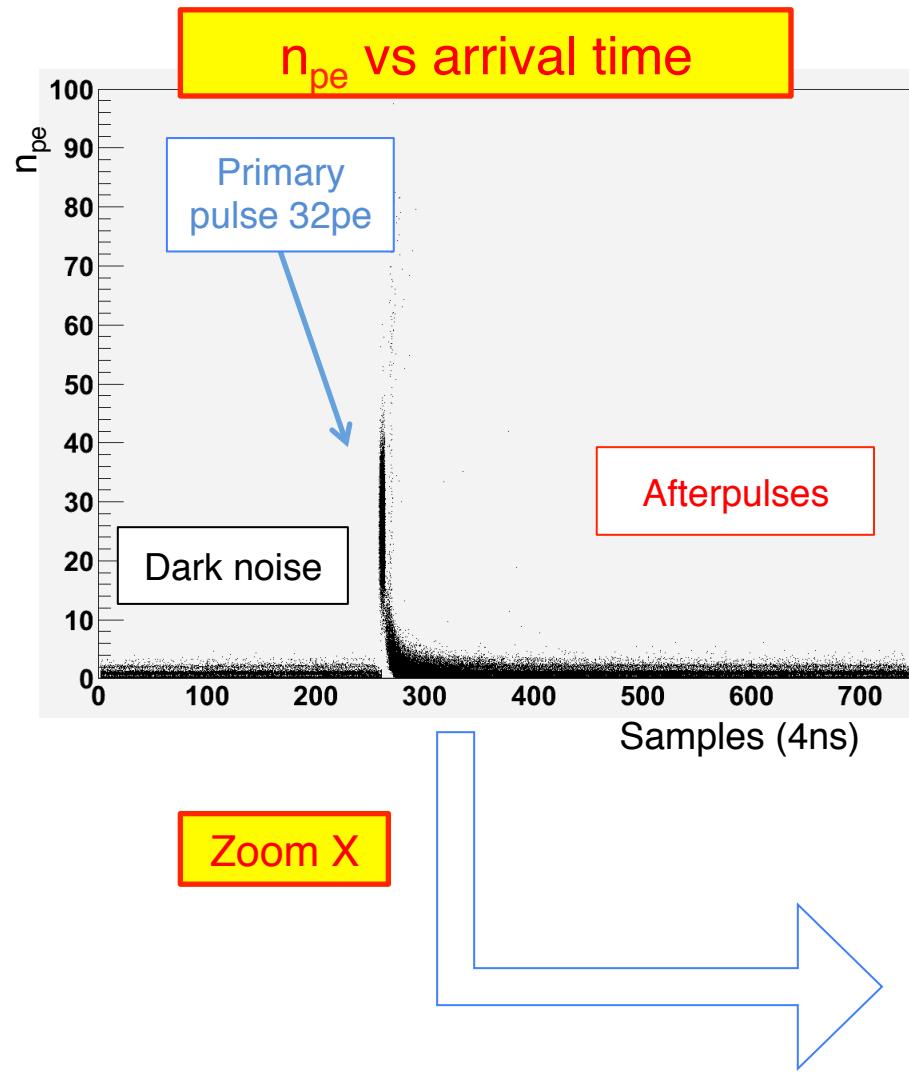
Thank you

Backup slides

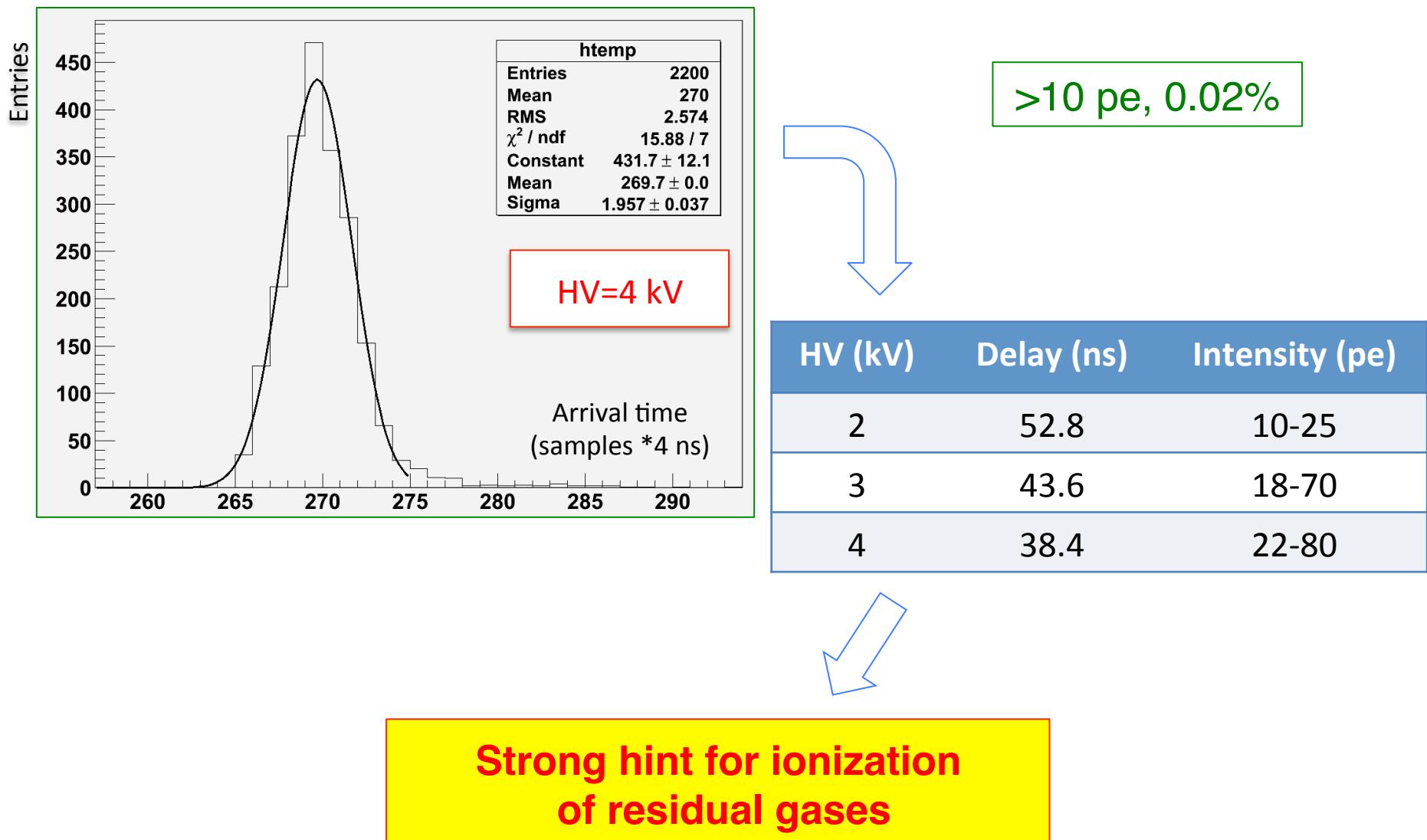
AP typical amplitude/1



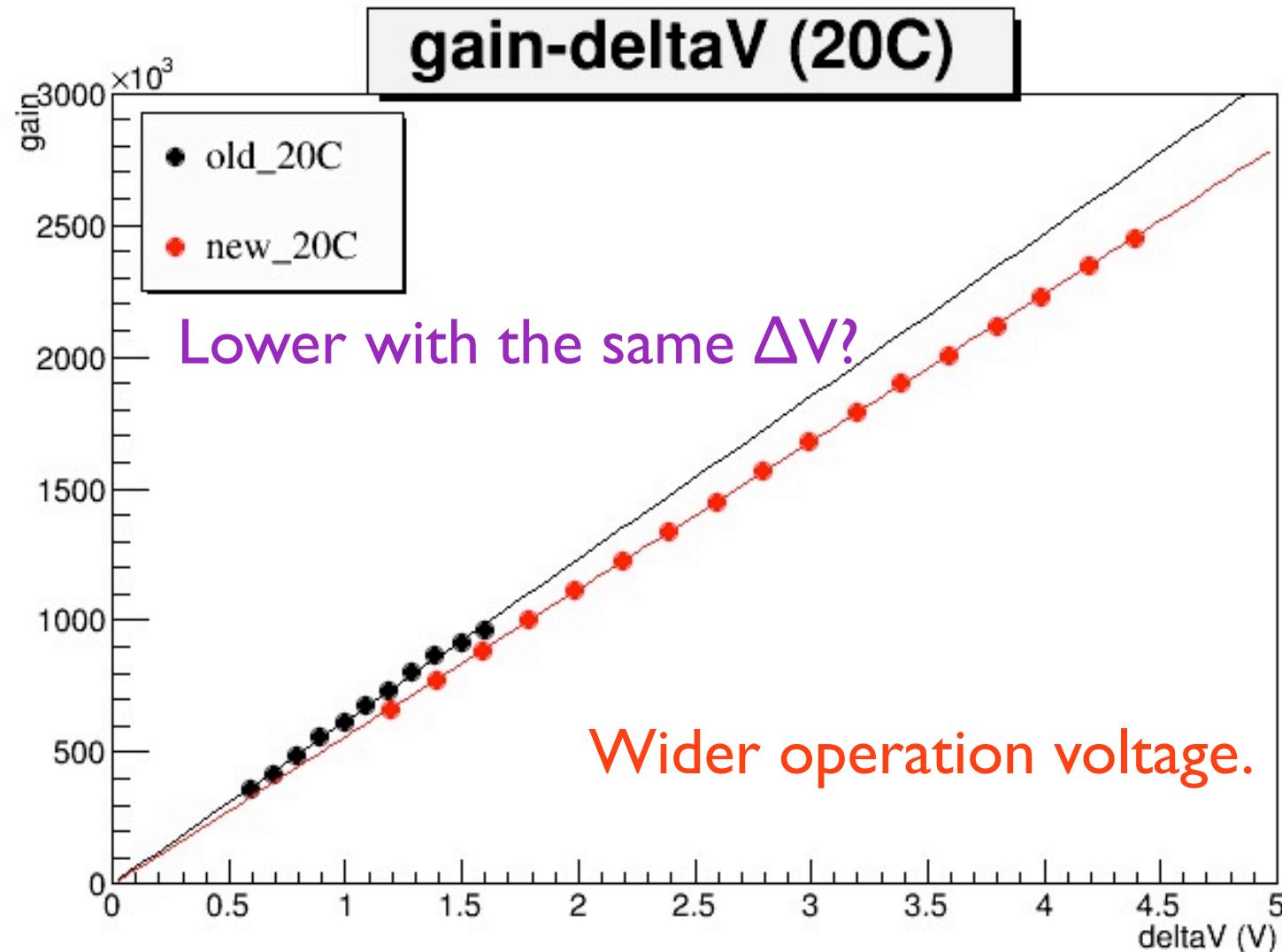
AP typical amplitude/2



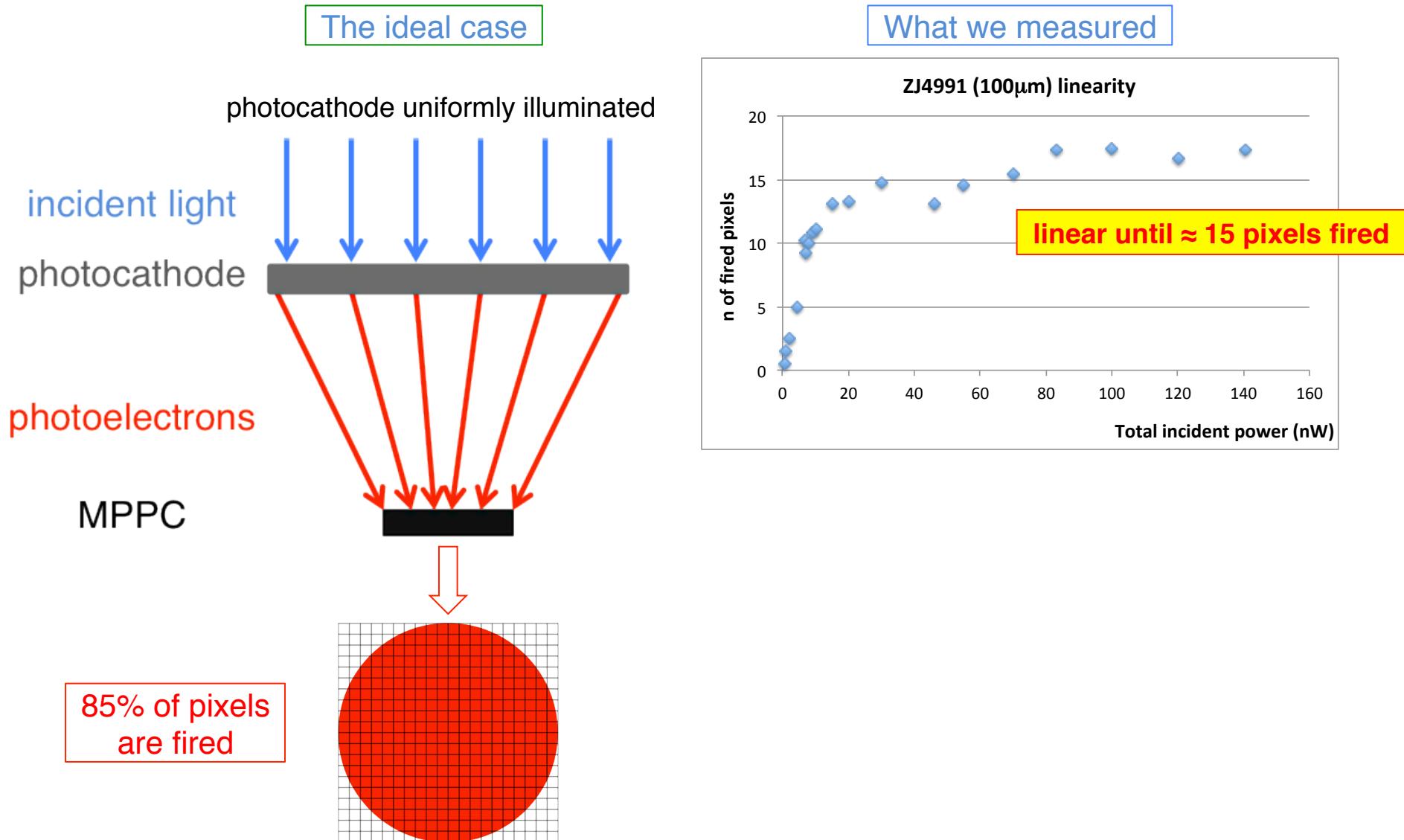
High intensity AP time distribution



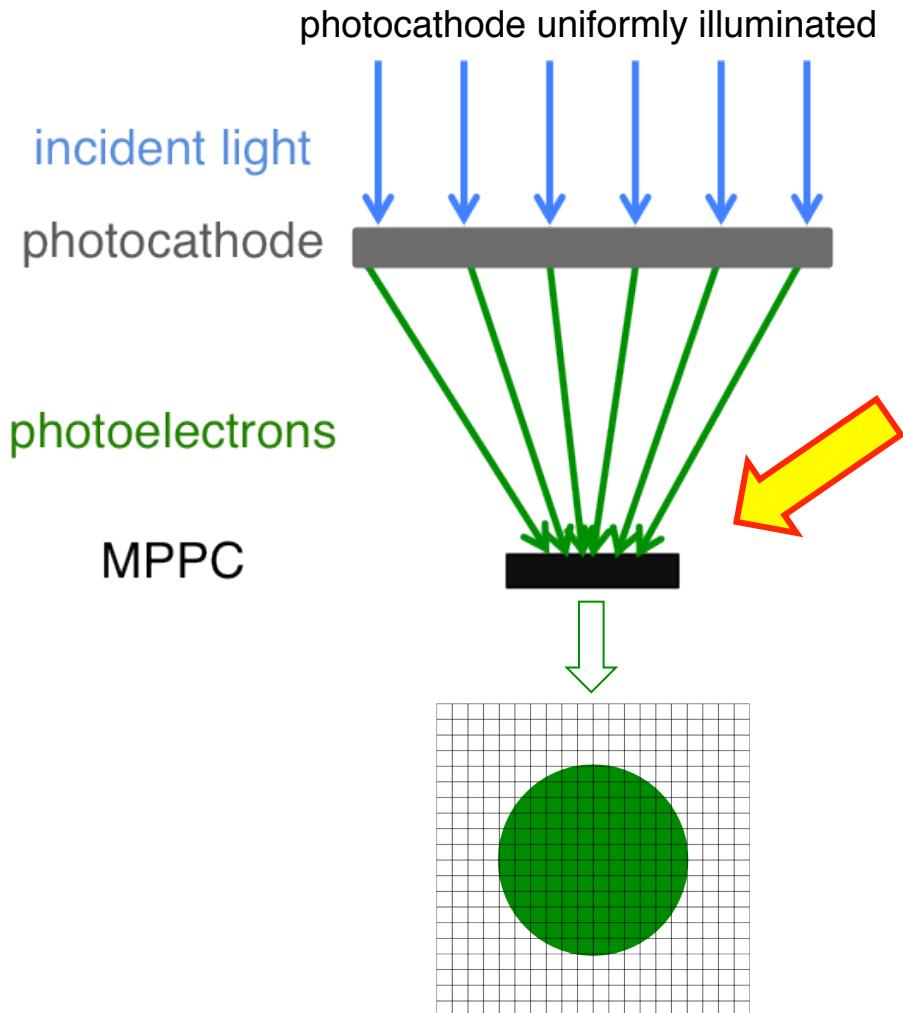
New generation MPPC gain



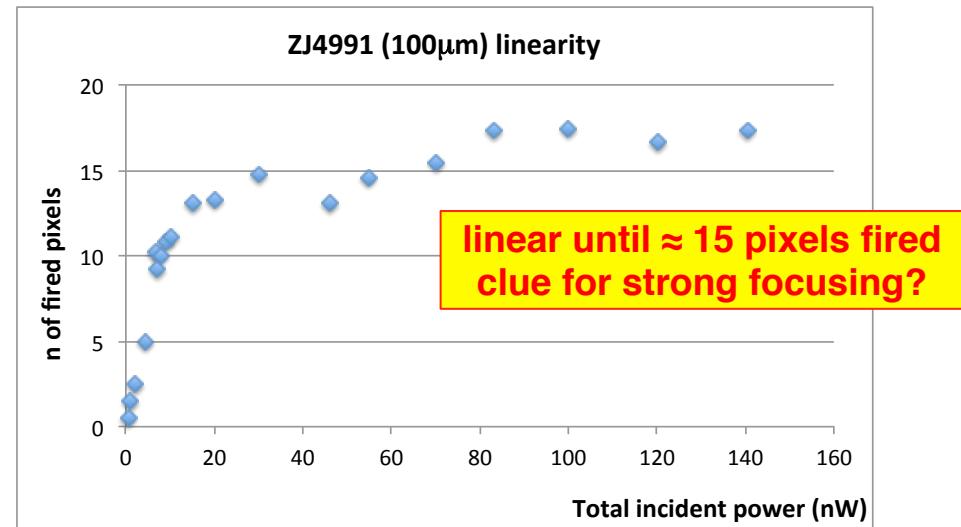
Linearity



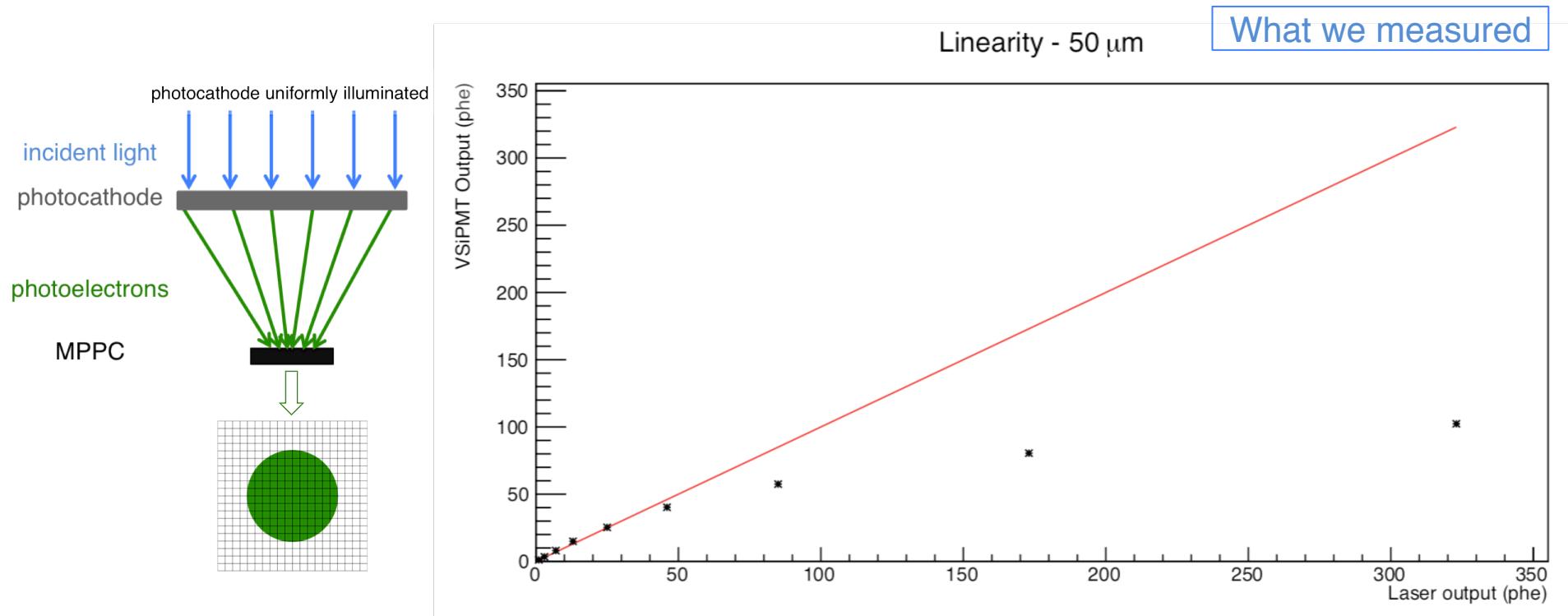
Linearity



What we measured



Linearity



ZJ4991 (100μm) has a too limited linearity

Optimal solution: 25μm – 50μm pixel size MPPC with improved Fill Factor for QE maximization

Time structure of afterpulses

Peaks arrival time distribution

